

# MALTA CMOS sensor telescope: new developments and recent measurements

Philip Allport, Ignacio Asensi Tortajada, Daniela Bortoletto, Craig Buttar, Valerio Dao, Roberto Cardella, Florian Dachs, Domonik Dobrijevic, Mateusz Dyndal, Leyre Flores Sanz de Aedo, Patrick Freeman, Andrea Gabrielli, Abhishek Sharma, Heidi Sandaker, Heinz Pernegger, Petra Riedler, Milou van Rijnbach, Carlos Solans Sanchez, Walter Snoeys, Tomislav Suligoj, Jose Torres Pais, Marlon Barbero, Pierre Barrillon, Patrick Breugnon, Pierre Pangaud, Yavuz Degerli, Amr Habib, Tomas Hemperek, Toko Hirono, Magdalena Munker, Philippe Schwemling, Tianyang Wang, Norbert Wermes, Kostas Moustakas

**Andrea Gabrielli**  
CERN



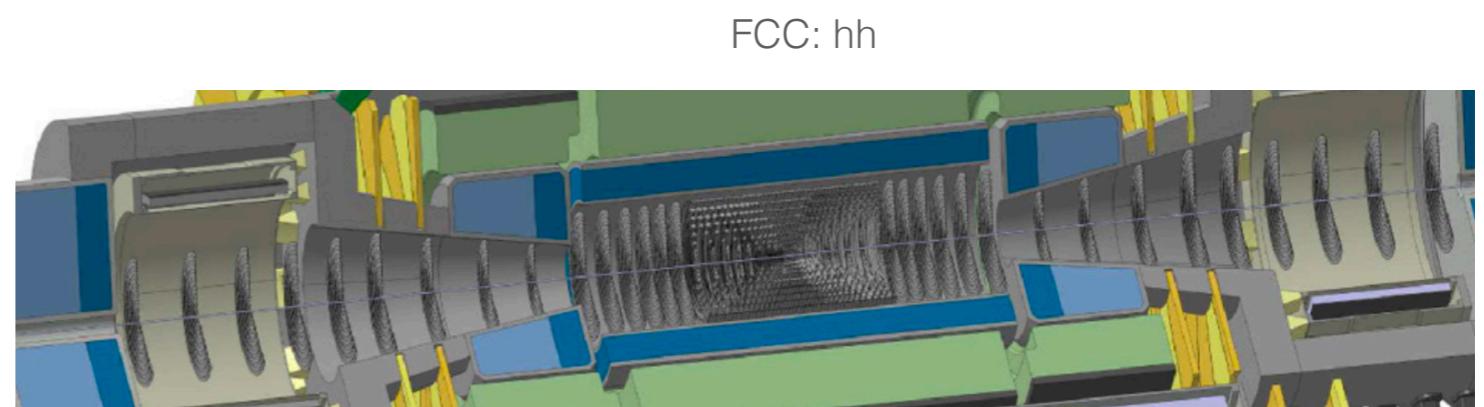
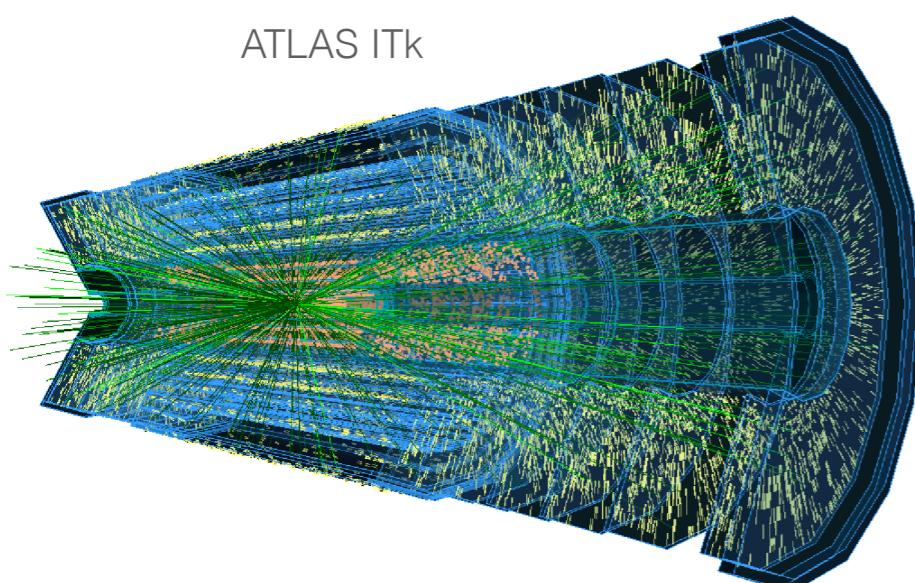
*MALTA Single Chip Testboard*

# CMOS motivation

- requirements for future HEP detectors are very challenging:
  - extreme radiation tolerance
  - very fast response
  - very large surface
  - very thin
  - high granularity

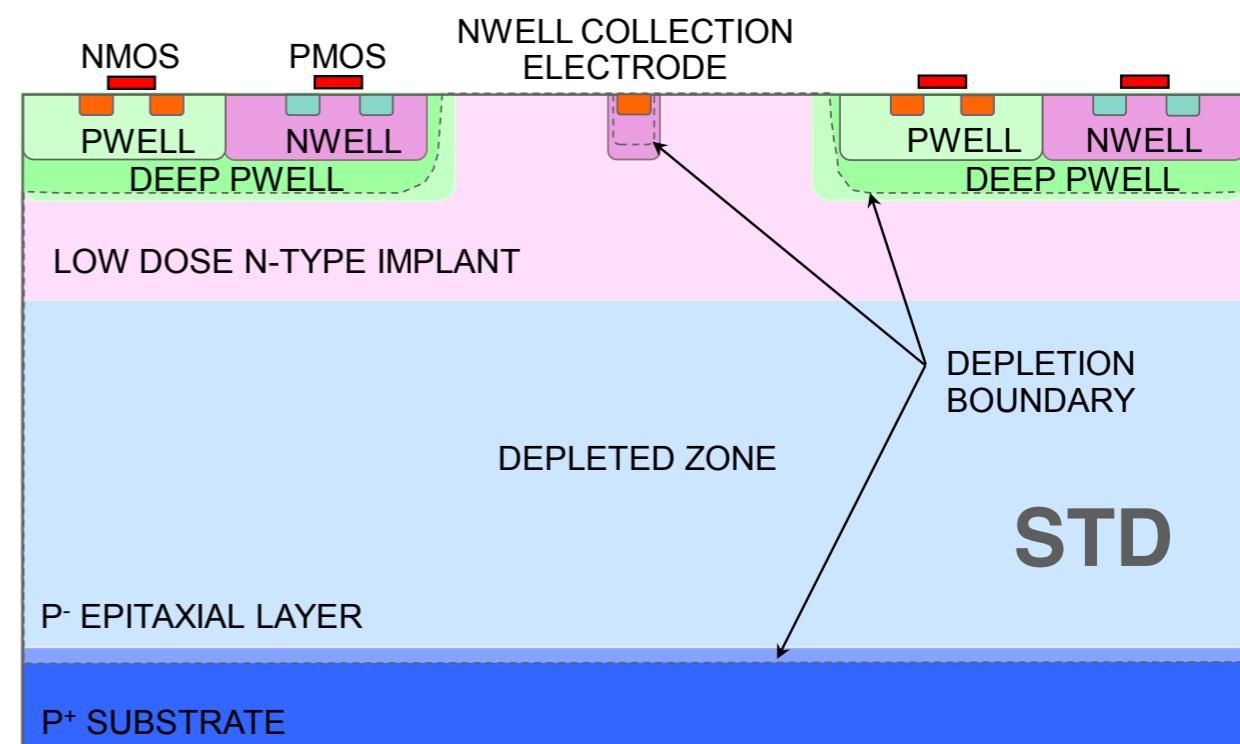
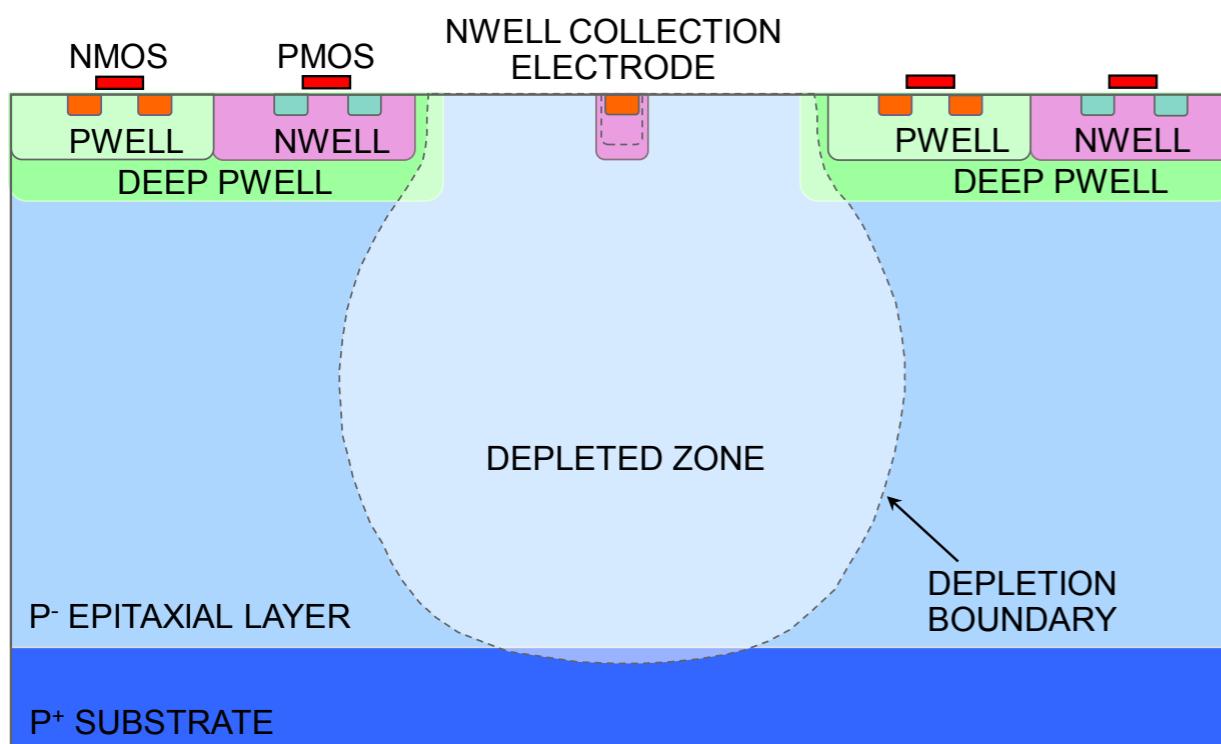
Parameter	Exp.	LHC	HL-LHC	SPS	FCC-hh	FCC-ee	CLIC 3 TeV
Fluence [ $n_{eq}/cm^2/y$ ]	$N \times 10^{15}$	$10^{16}$	$10^{17}$	$10^{16} - 10^{17}$	$<10^{10}$	$<10^{11}$	
Max. hit rate [ $s^{-1}cm^{-2}$ ]	100 M	2-4 G****)	8 G****)	20 G	20 M ***)	240k	
Surface inner tracker [ $m^2$ ]	2	10	0.2	15	1	1	
Surface outer tracker [ $m^2$ ]	200	200	-	400	200	140	
Material budget per detection layer [ $X_0$ ]	0.3%*) - 2%	0.1%*) - 2%	2%	1%	0.3%	0.2%	
Pixel size inner layers [ $\mu m^2$ ]	100x150-50x400	~50x50	~50x50	25x50	25x25	$\sim 25 \times 25$	
BC spacing [ns]	25	25	$>10^9$	25	20-3400	0.5	
Hit time resolution [ns]	$\sim 25-1k^*)$	0.2**)-1k*)	0.04	$\sim 10^{-2}$	$\sim 1k^{***})$	$\sim 5$	

\*) ALICE requirement   \*\*) LHCb requirement   \*\*\*) At Z-pole running   \*\*\*\*) max. output rate for LHCb/high intensity flavour experiments: 300-400 Gbit/s/cm<sup>2</sup>



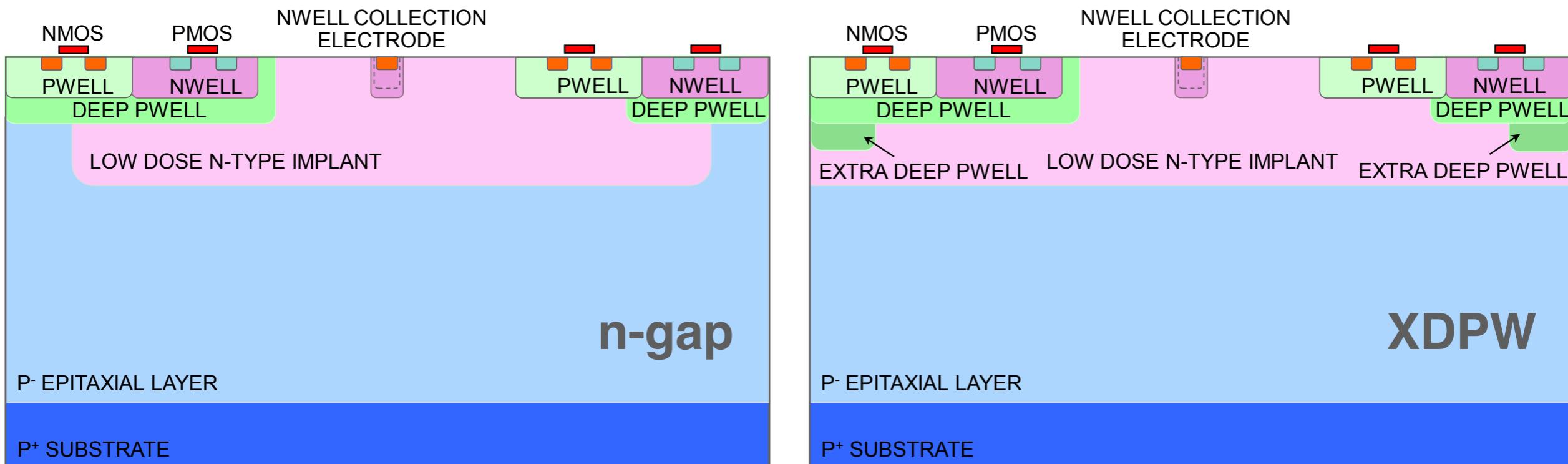
# Tower Semiconductor 180nm CMOS sensors

- Towejazz process:
  - high-resistivity Epi layer, 25  $\mu\text{m}$  depletion  $\rightarrow \sim 1500 \text{ e-}$  for MIP, high signal to noise ratio ( $\sim 20$ )
- modified process:
  - extra low dose n-type layer to improve depletion under the deep p-well, better radiation tolerance



# Tower Semiconductor 180nm CMOS sensors

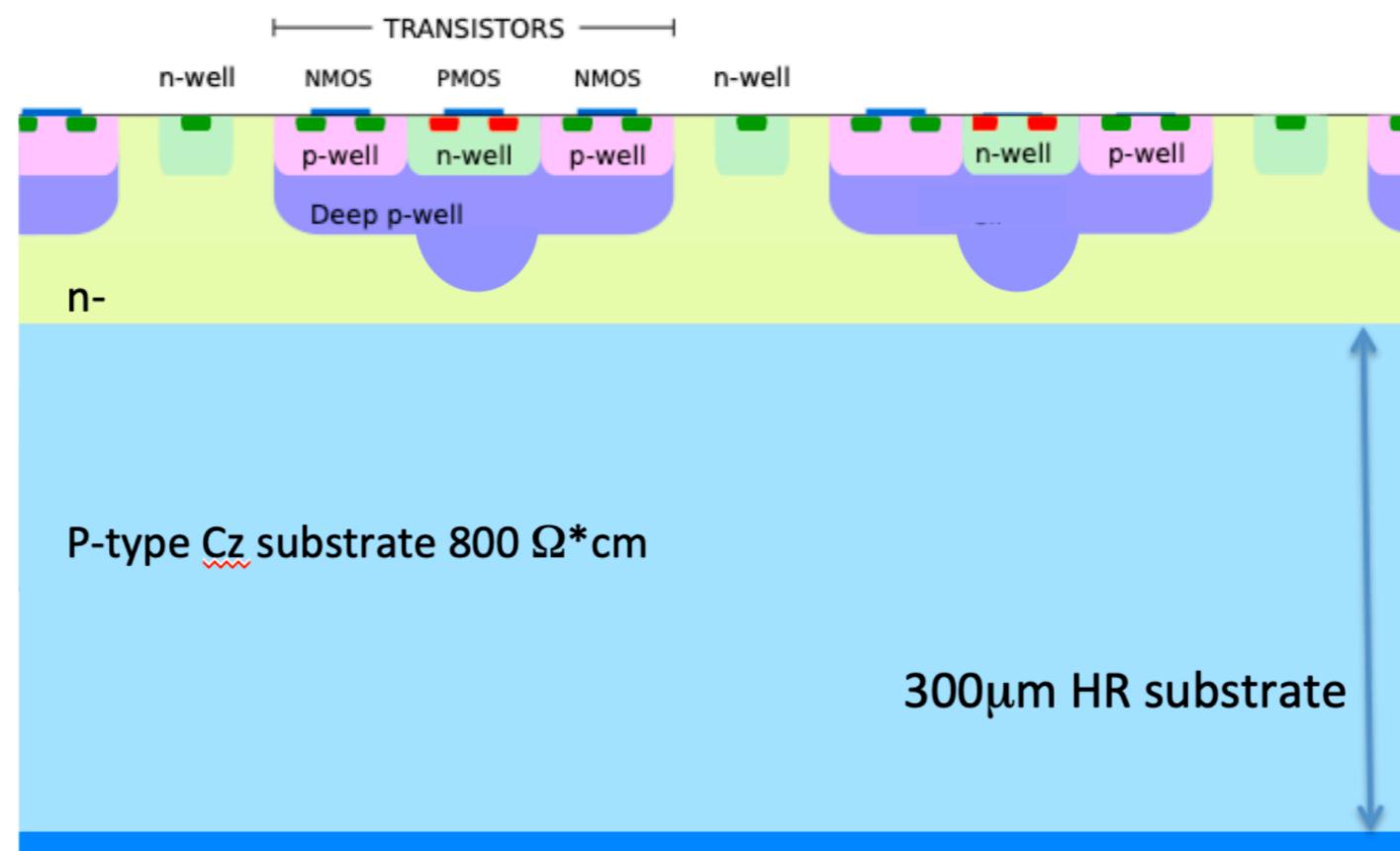
- special layouts for deep p and n wells to optimize field configuration and charge collection: increase lateral field near pixel edge to “focus” charge to electrode:
  - gap in the n-layer: 4  $\mu\text{m}$  gap in the low dose n-layer
  - ‘extra-deep p-well’ layer: 5  $\mu\text{m}$  wide additional p-well implant



H.Pernegger HSTD12  
M. Dyndal,JINST 15 (2020) P02005  
M. Mironova, NIM A 956 (2020) 163381  
Magdalena, M.Munker PIXEL 2018

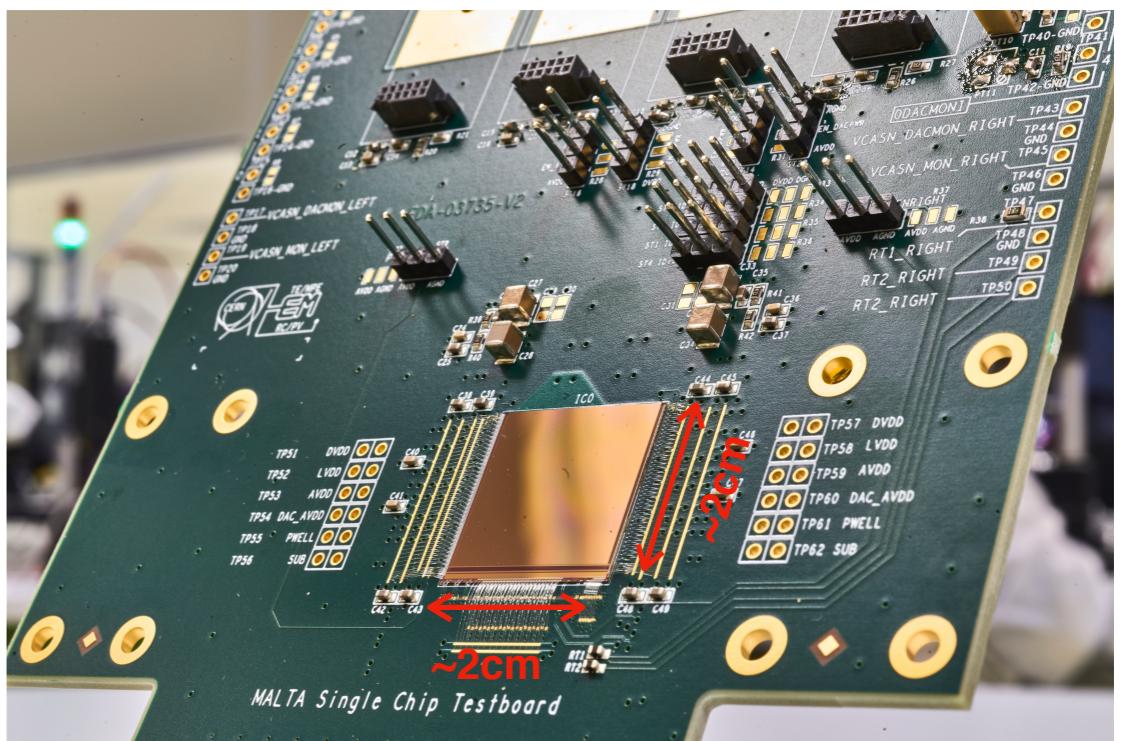
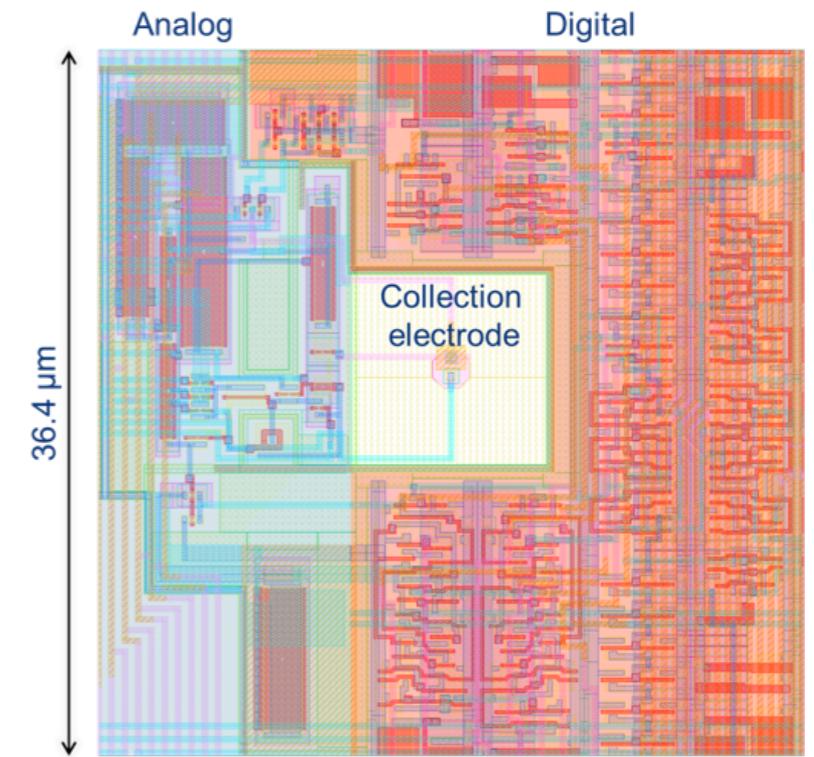
# Tower Semiconductor 180nm CMOS sensors

- MALTA with high resistivity Czochralski(Cz) substrate material
- significant larger depletion and signal:
  - higher radiation hardness
  - high operation voltage up to 50V -> high depletion depth



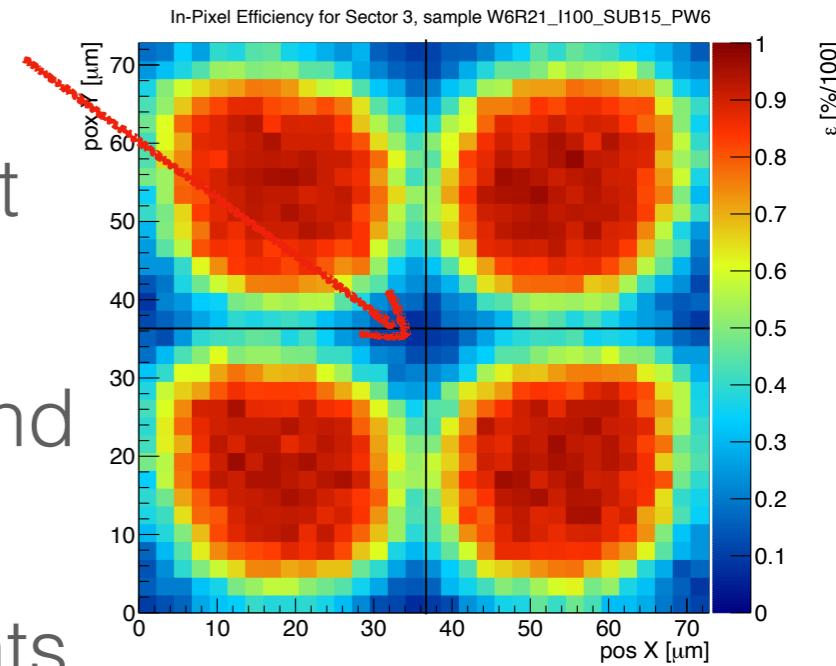
# MALTA pixel detector

- matrix 512 x 512 pixels of 36.4 x 36.4  $\mu\text{m}^2$  size
- small collection electrode of 2-3  $\mu\text{m}^2$  to achieve minimal input capacitance <3fF
- 3.4-4  $\mu\text{m}$  spacing between electrode and electronics: low cross talk
- asynchronous architecture
- very low power consumption:
  - 1  $\mu\text{W}/\text{pixel}$  analog power
  - 70  $\text{mW}/\text{cm}^2$  analog power
  - 10  $\text{mW}/\text{cm}^2$  digital power
- parallel read-out bus 37bit
- Xilinx Virtex/Kintex FPGA for readout

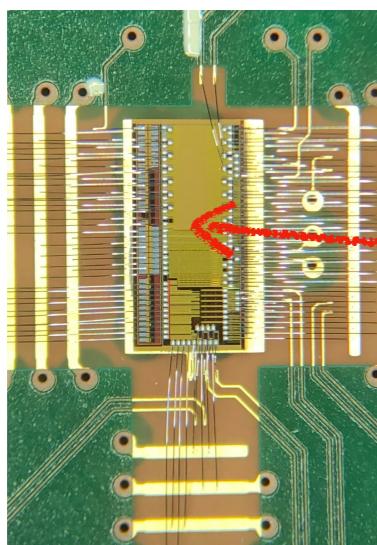


# Malta history

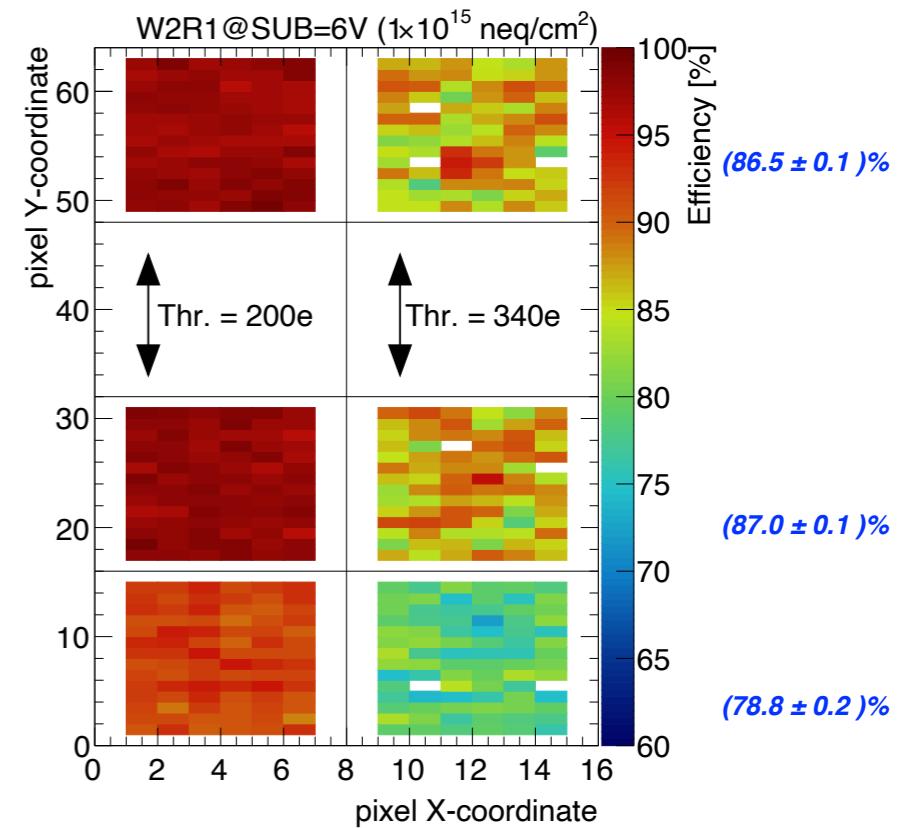
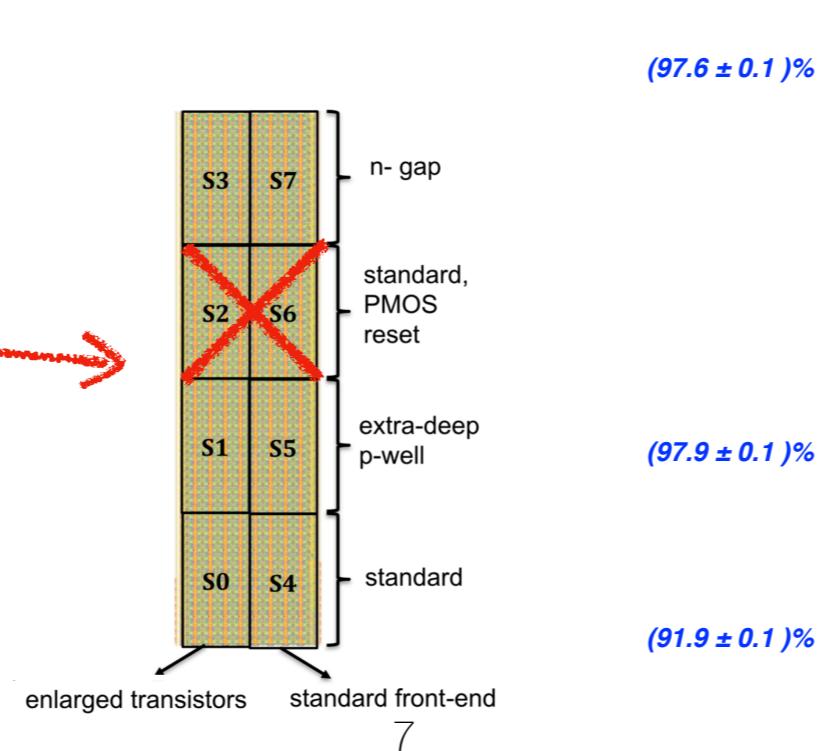
- 2018, first MALTA: after neutron irradiation the collection efficiency is degraded at pixel edges
- Jan 2019, MiniMALTA: smaller matrix version that changes the p-well extension to address the efficiency loss on corners and improved Front-End
- Aug 2019, reprocessed MALTA: large demonstrator with MiniMalta sensor improvements



MiniMALTA demonstrator  
5 mm x 1.7 mm

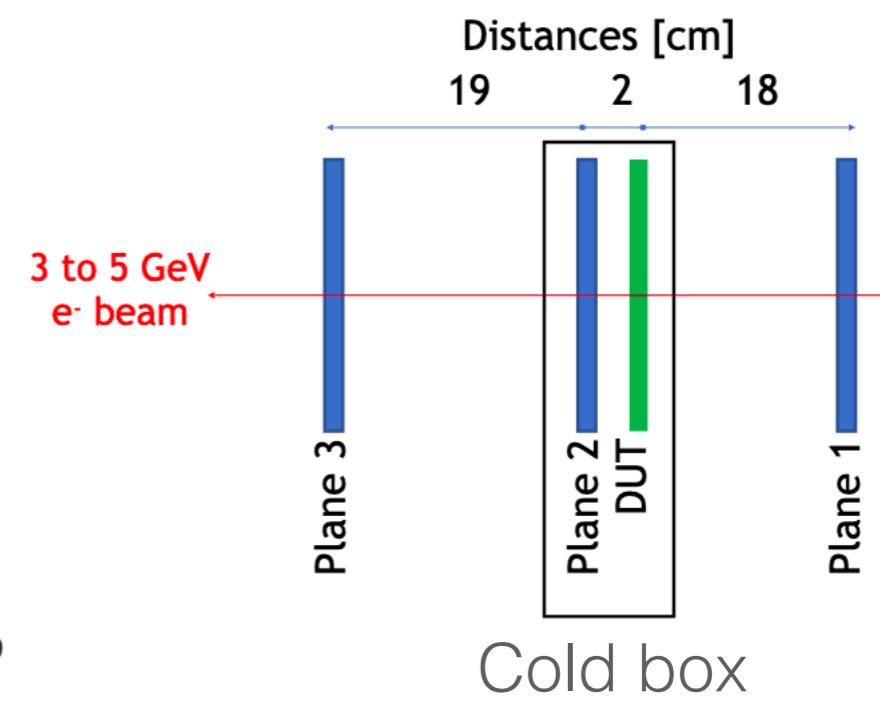
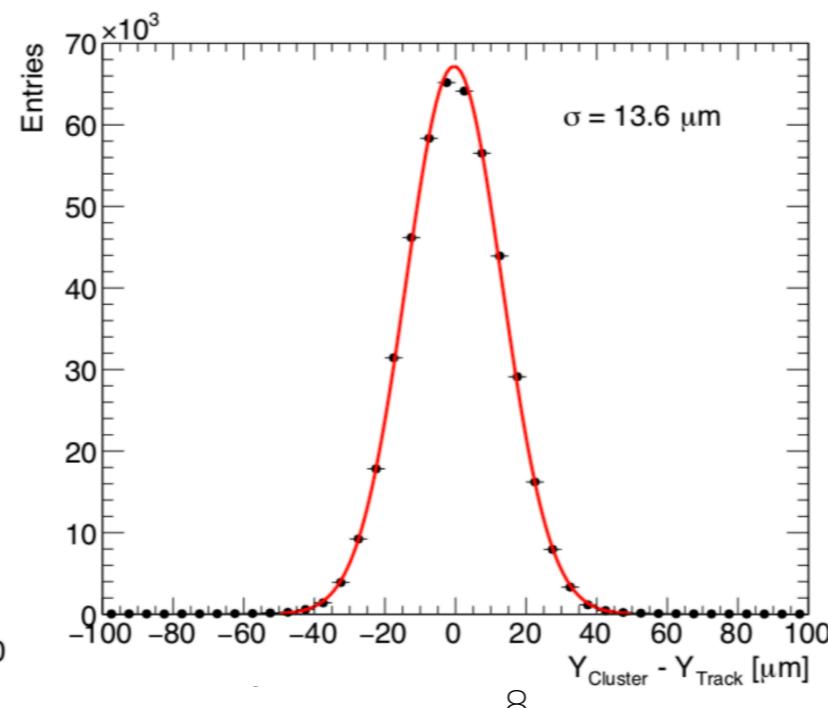
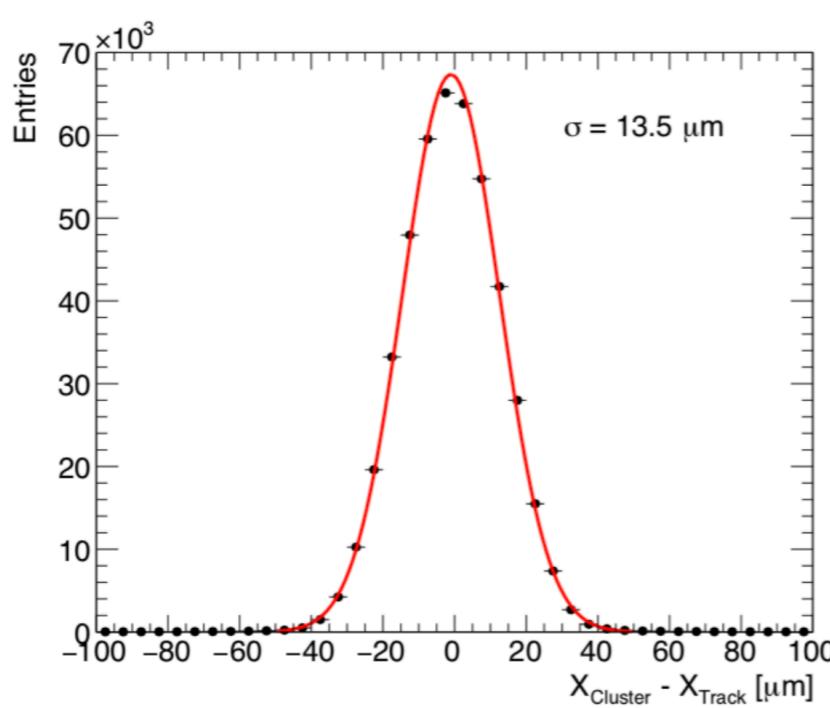
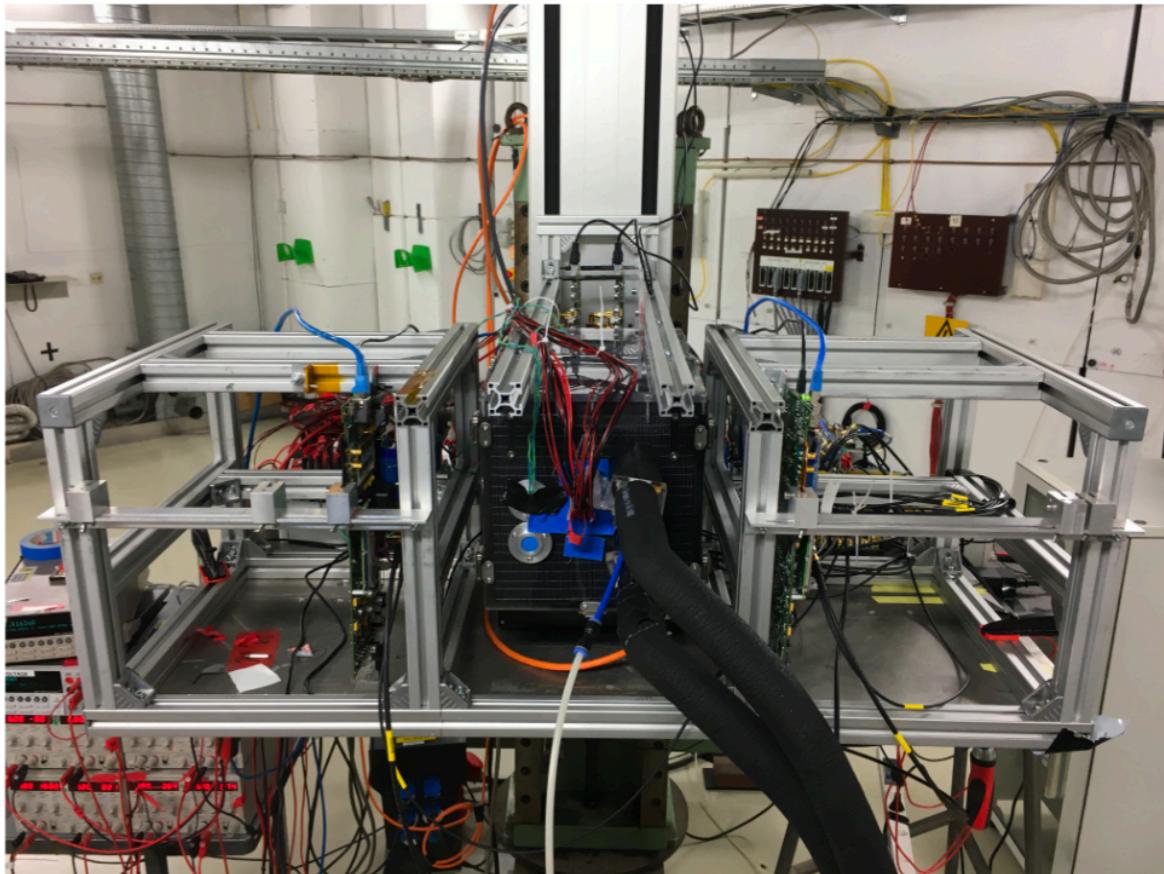


JINST 15 (2020) 02, P02005  
I. Asensi VERTEX (2020)



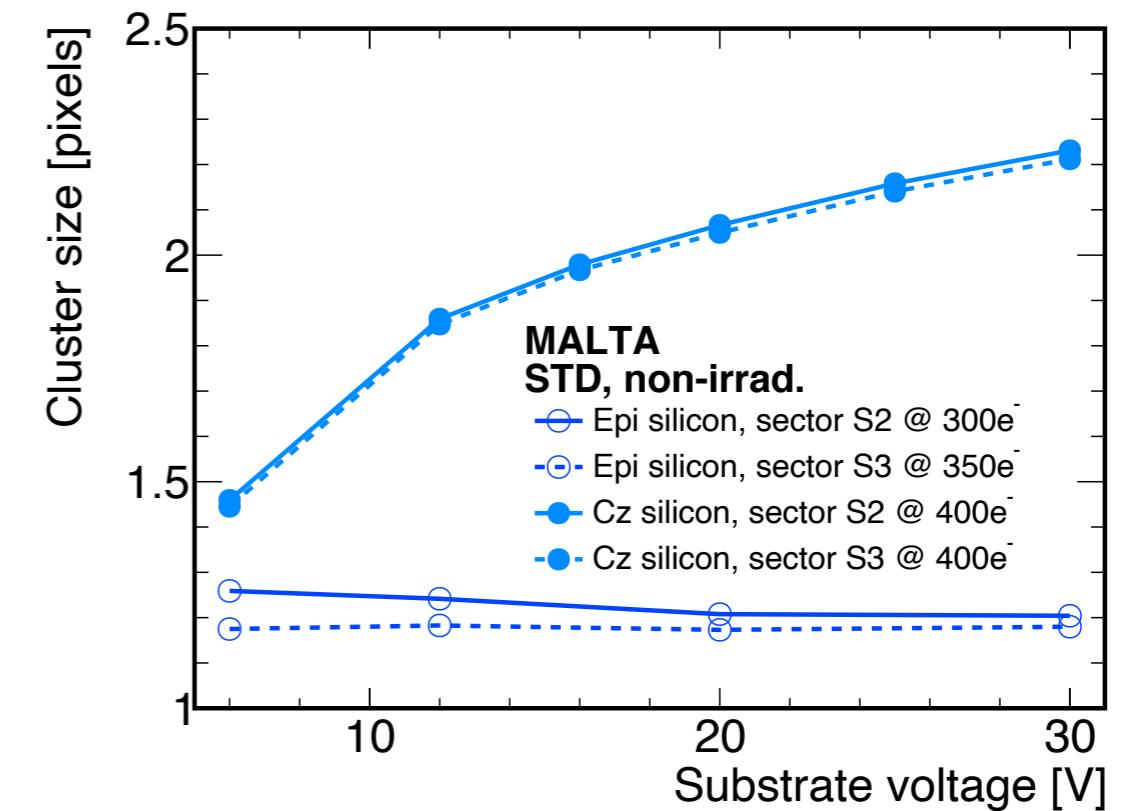
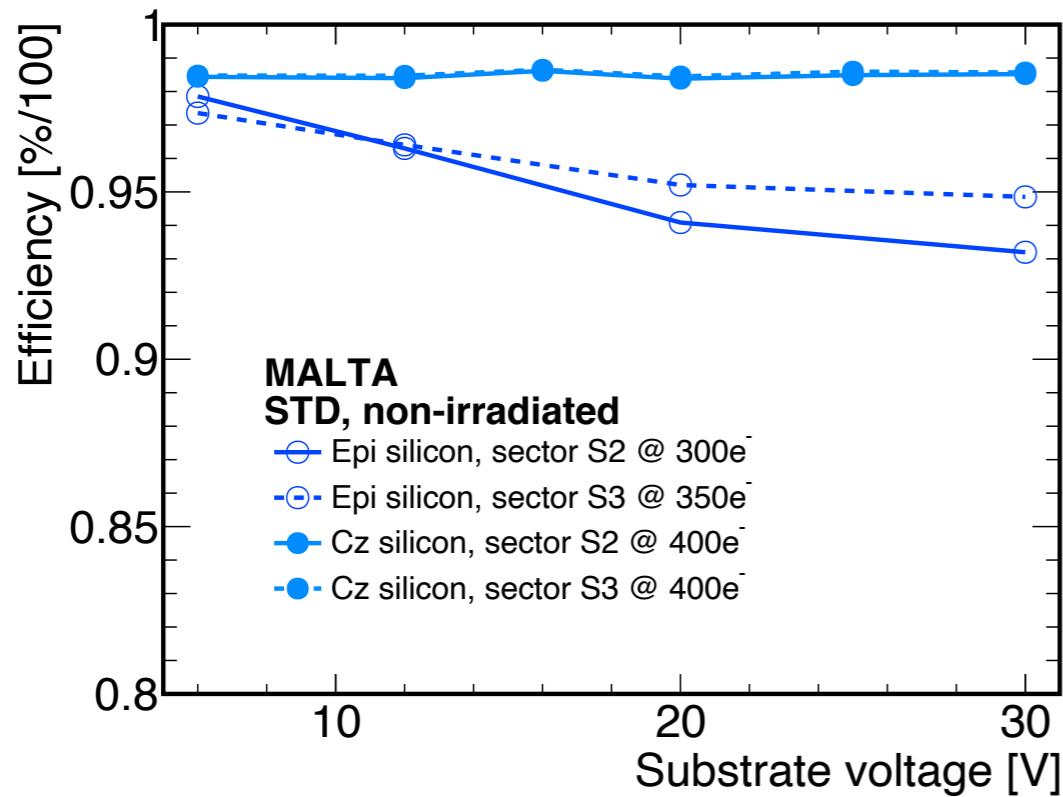
# MALTA telescope testbeam

- DESY testbeam energy = 3-4 GeV
- custom MALTA-based telescope
  - up to 7 MALTA tracking planes (100  $\mu\text{m}$  thick, 36  $\mu\text{m}$  pitch size)
  - triggering on planes with custom TLU with high flexibility
  - tracking performance  $\sim 13 \mu\text{m}$  residual width



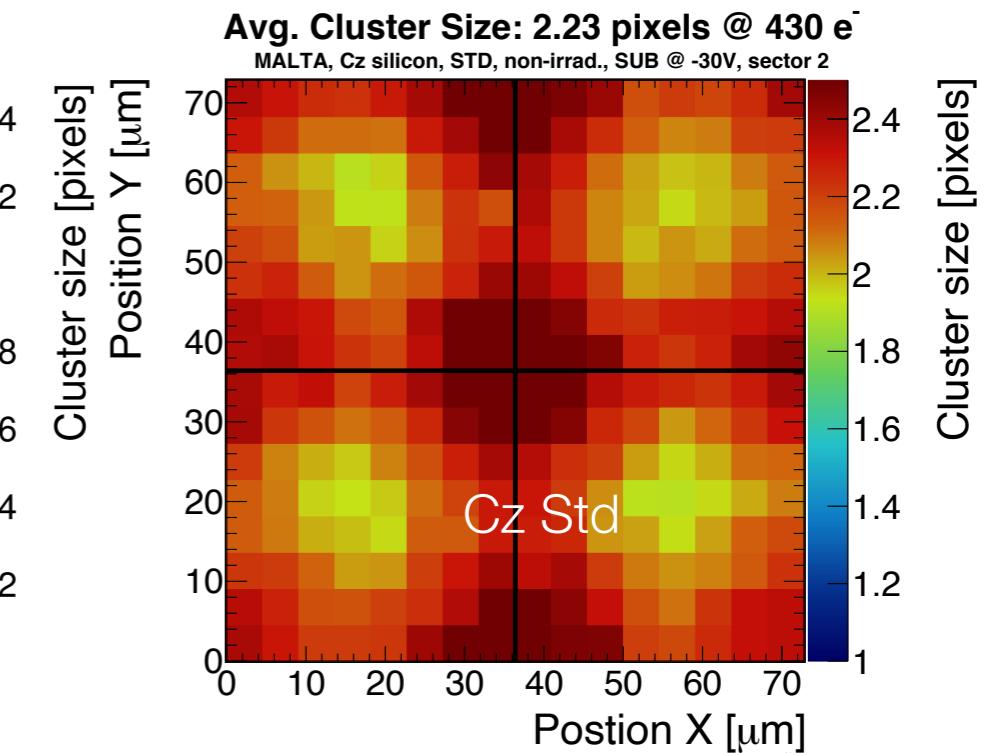
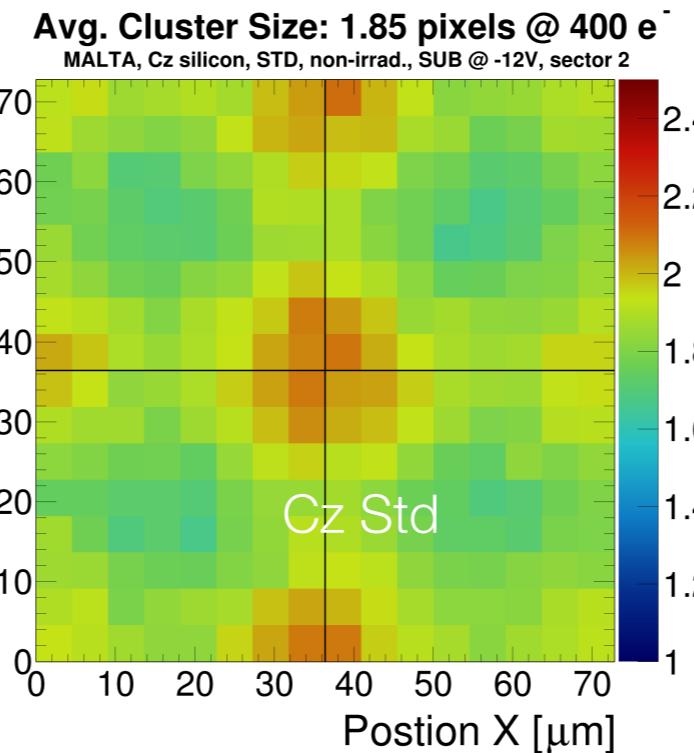
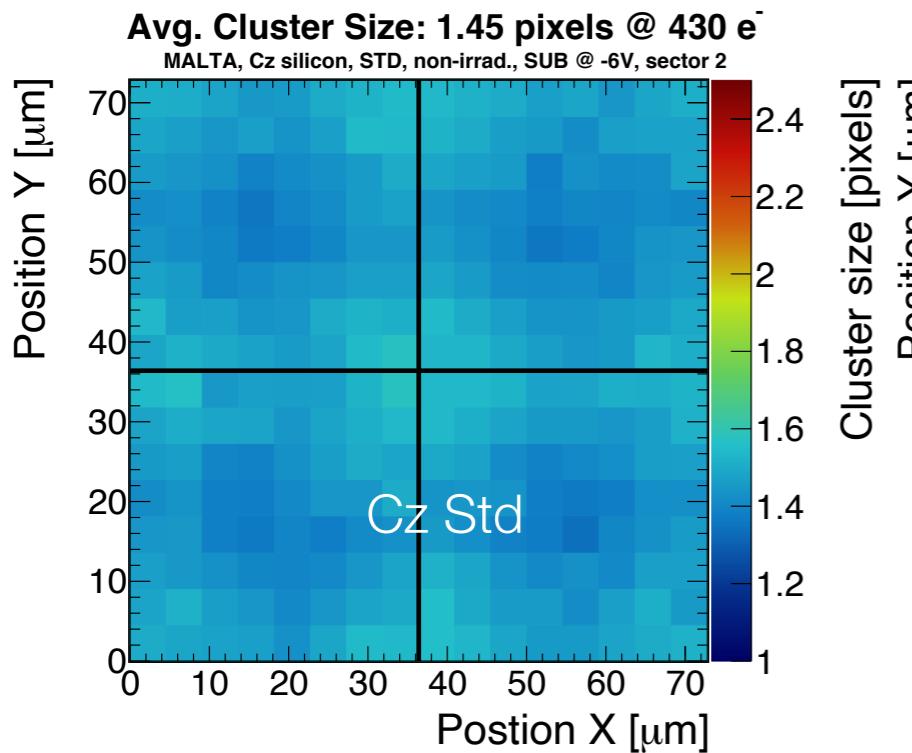
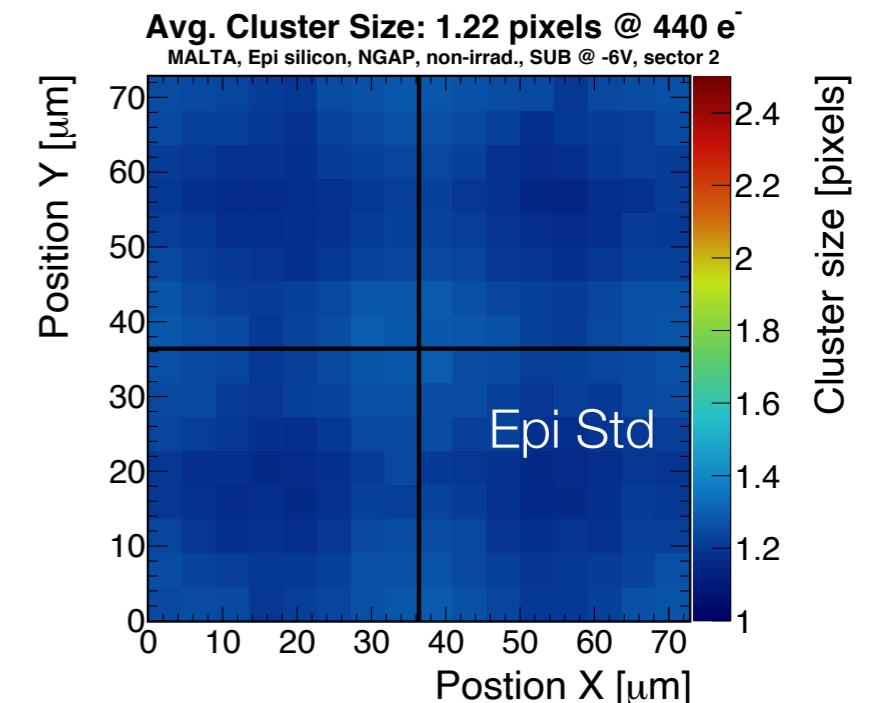
# MALTA non-irradiated chip

- efficiency vs substrate voltage:
  - Epi: no gain at high voltage (full depletion at 6V)
  - Cz: flat efficiency vs substrate voltage
- cluster size vs substrate voltage:
  - Epi: constant cluster size
  - Cz: smooth increase when increasing substrate voltage (more charge sharing in Cz material)



# MALTA non-irradiated chip

- in-pixel cluster size vs substrate voltage  
(shown as 2x2 pixel x-y dependency)
- Cz has larger cluster size and more charge collection sharing



6 V

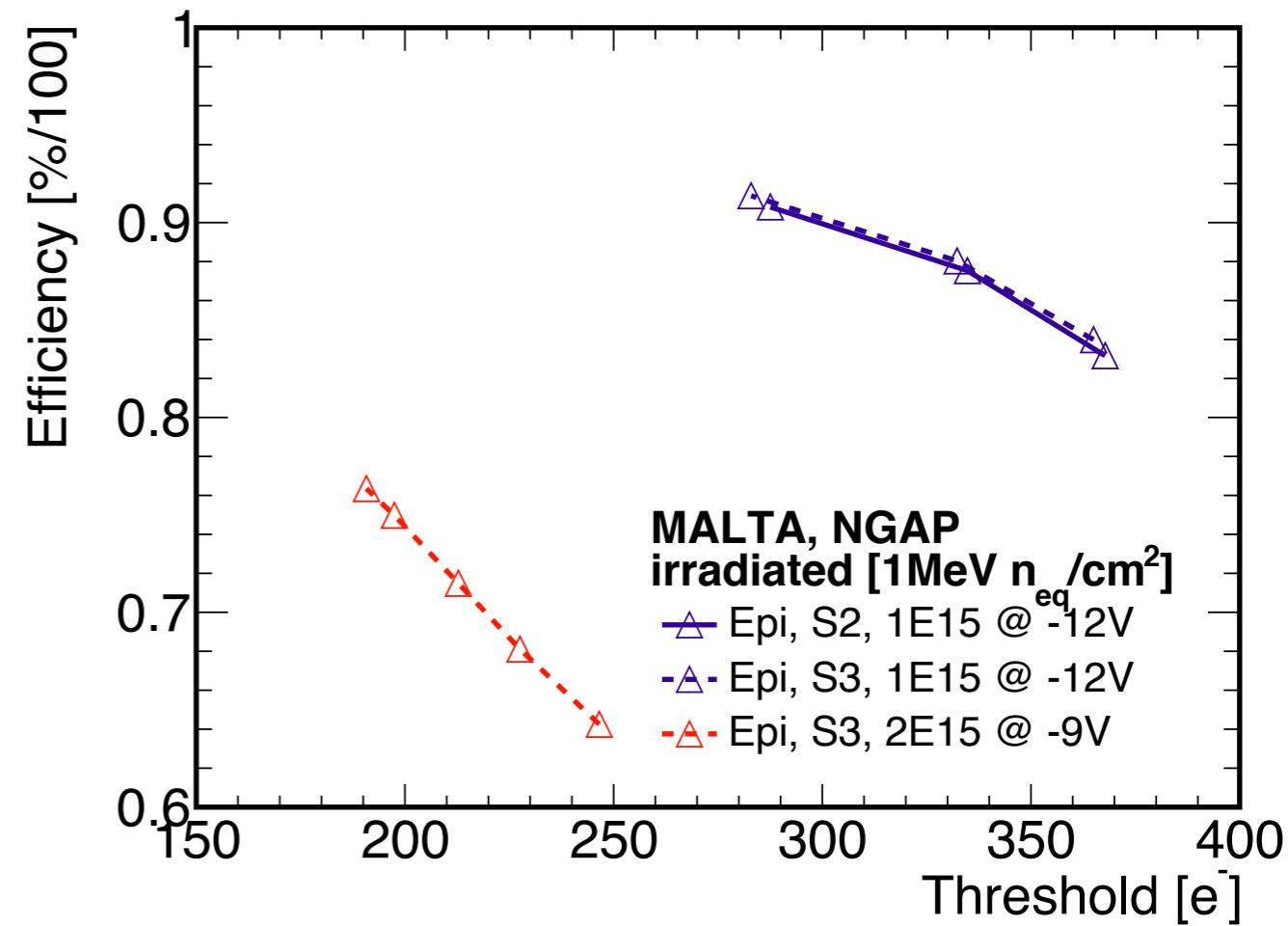
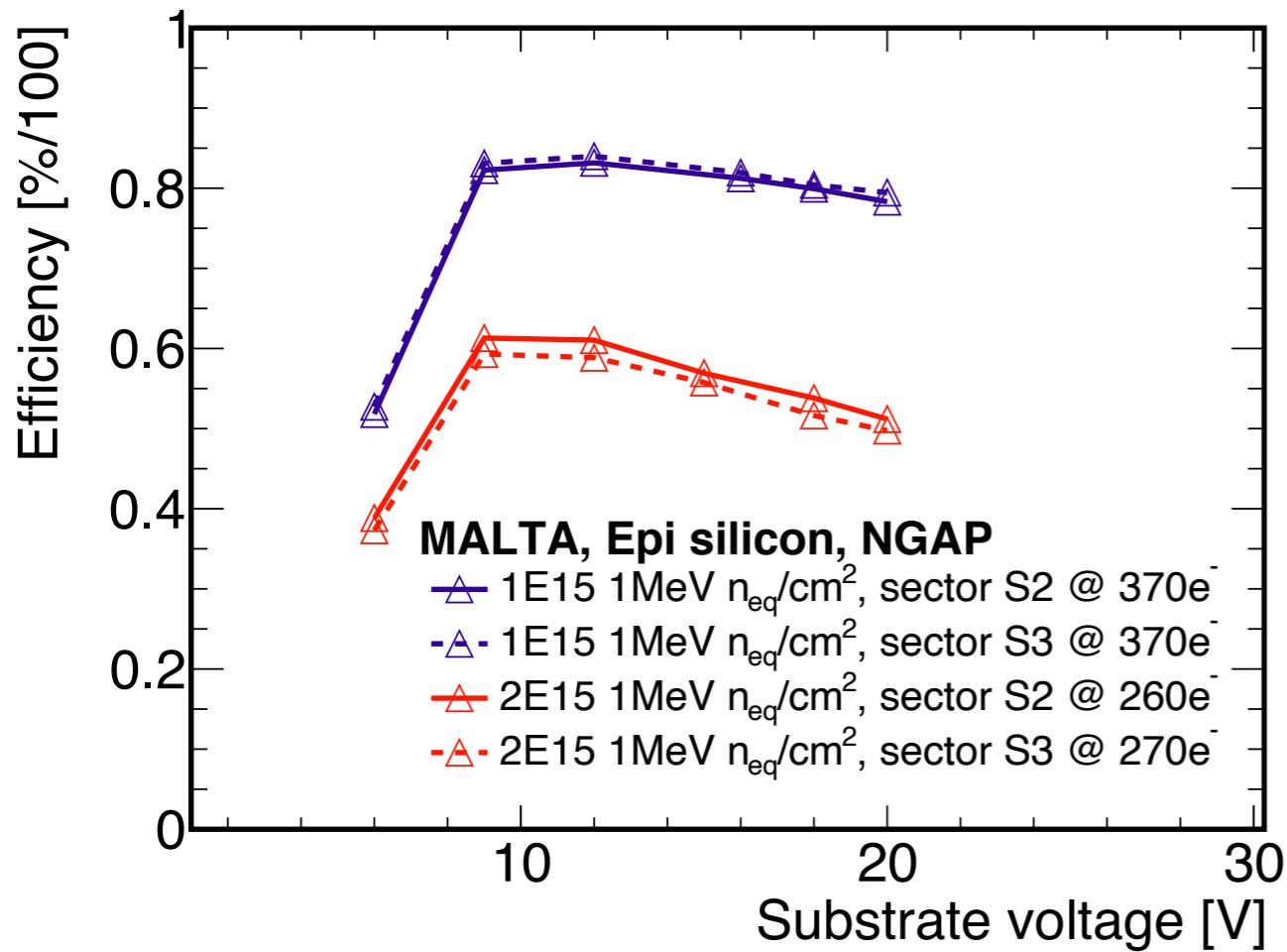
12 V

30 V

SUB V

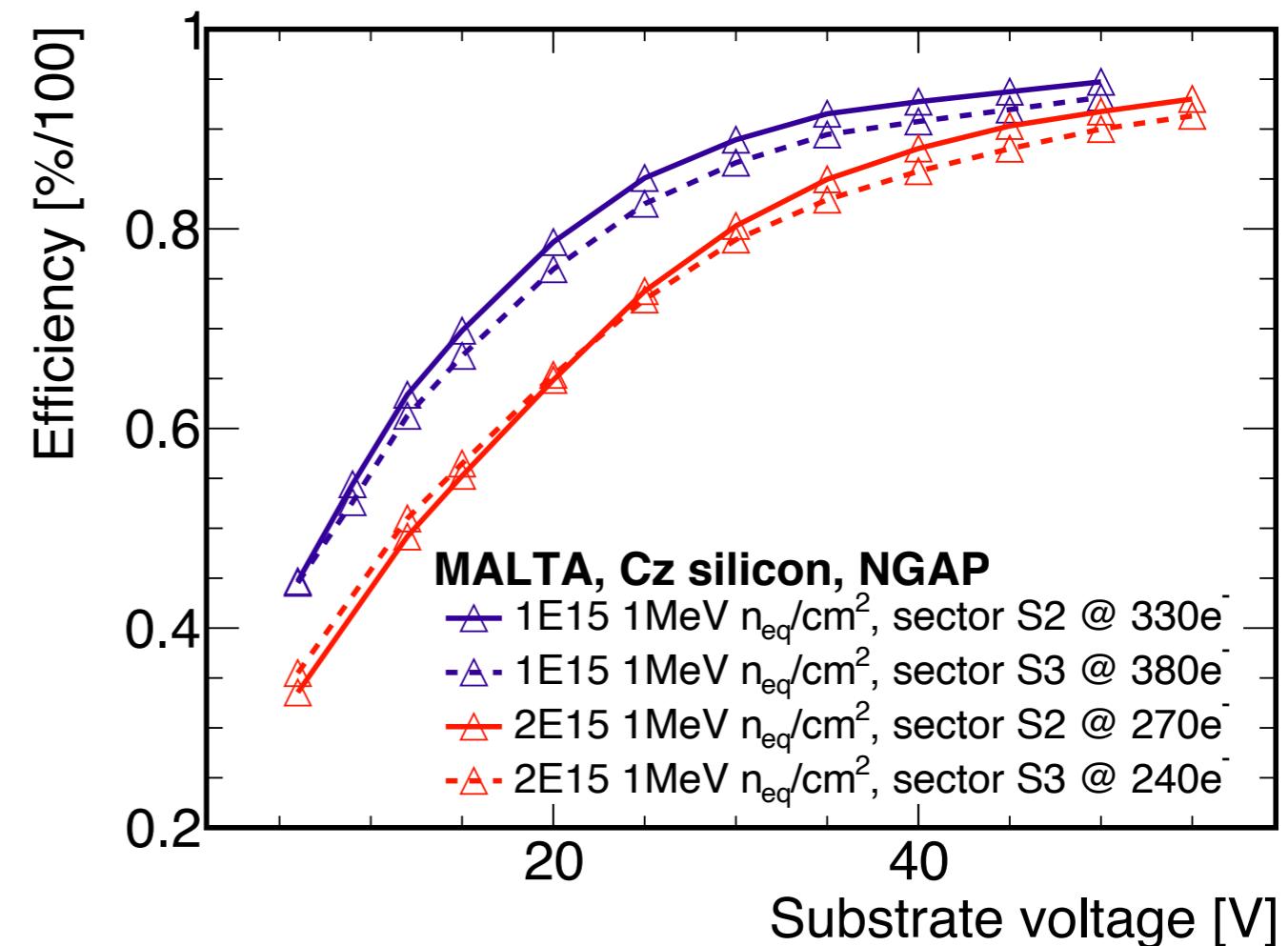
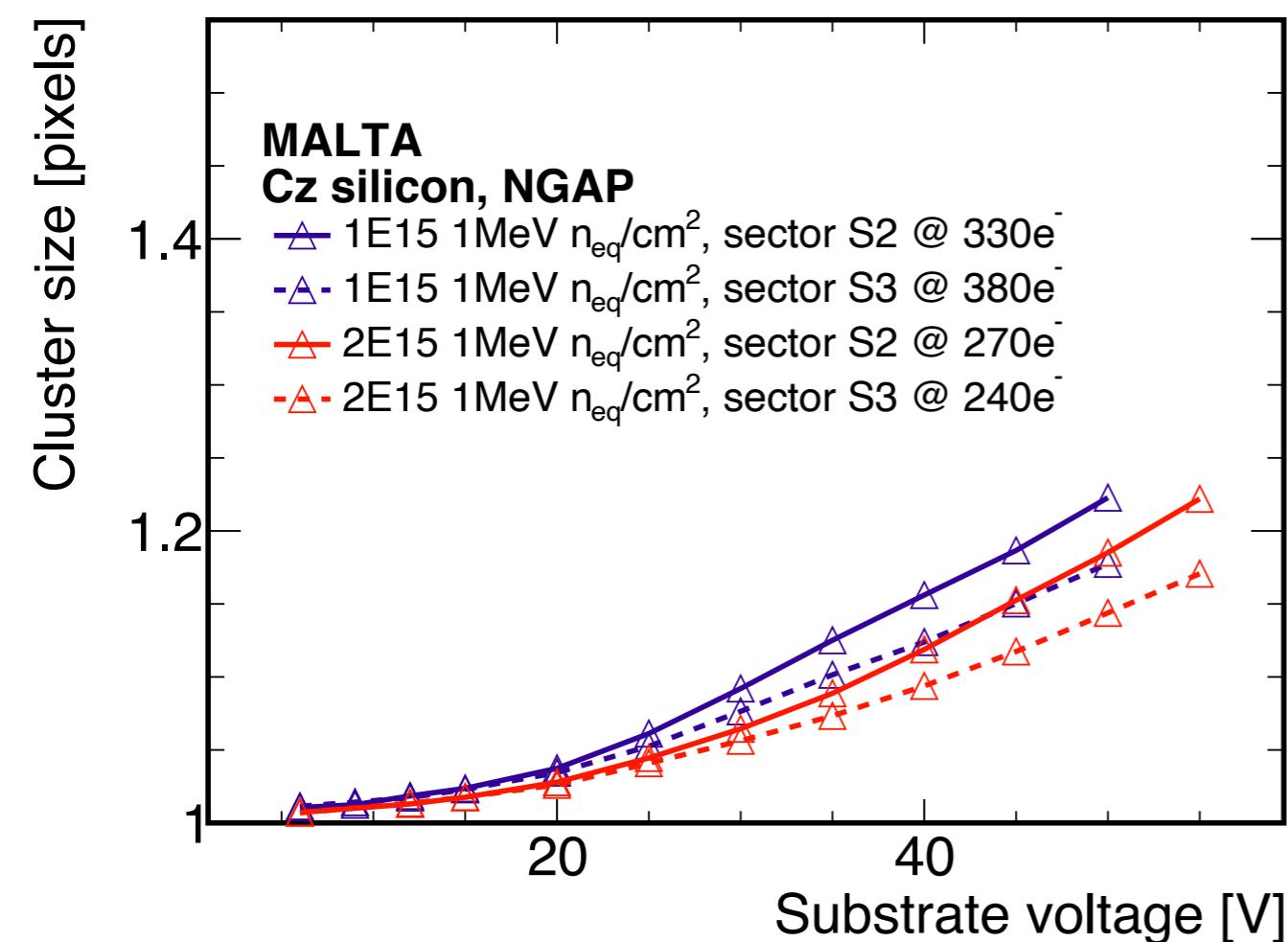
# MALTA irradiated chips

- Epi silicon sensor low efficiency for irradiated chip ( $1\text{e}^{15} \text{n}_{\text{eq}}/\text{cm}^2$ )  
~80% @-10 V @370 e-
- no gain with higher substrate voltage
- results consistent with previous MiniMalta measurements



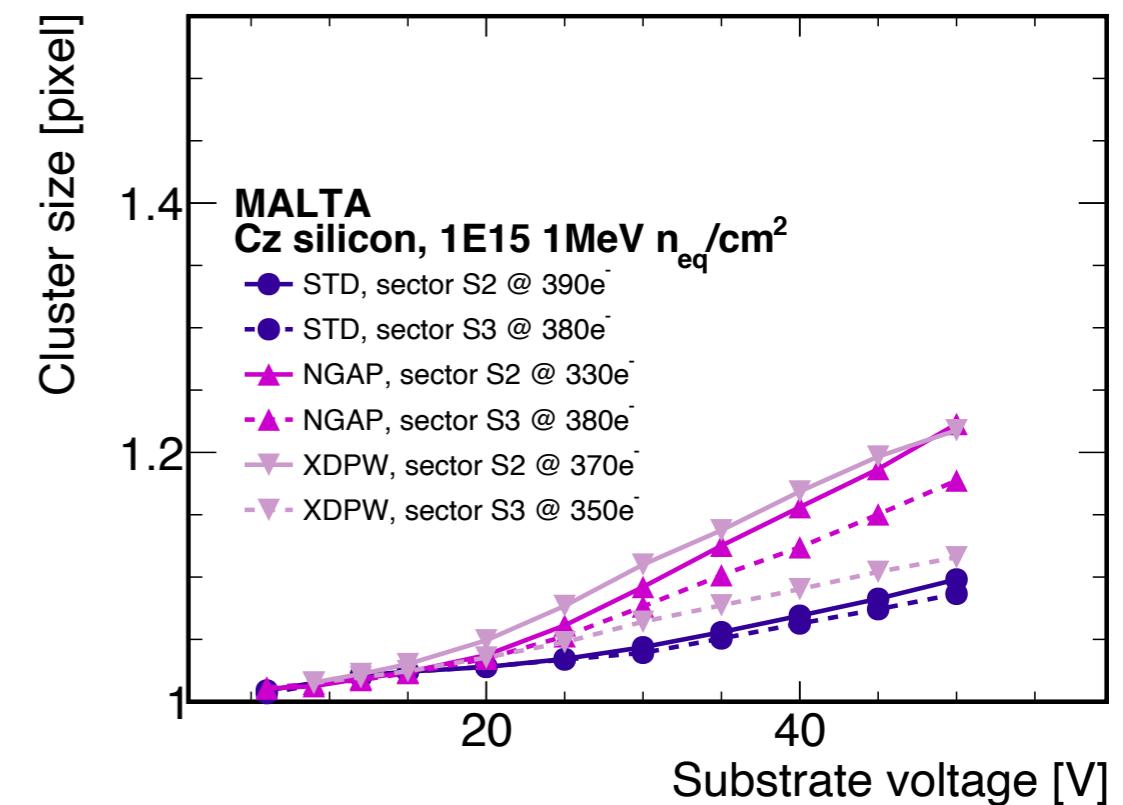
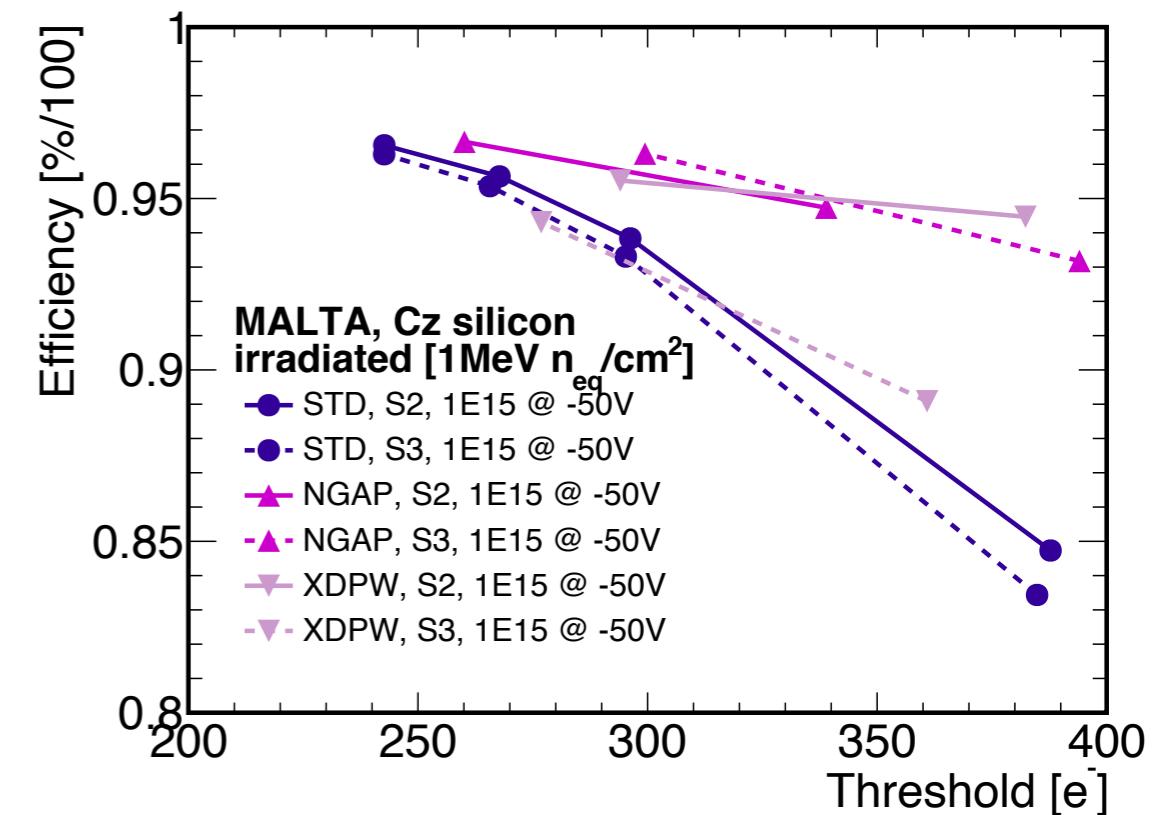
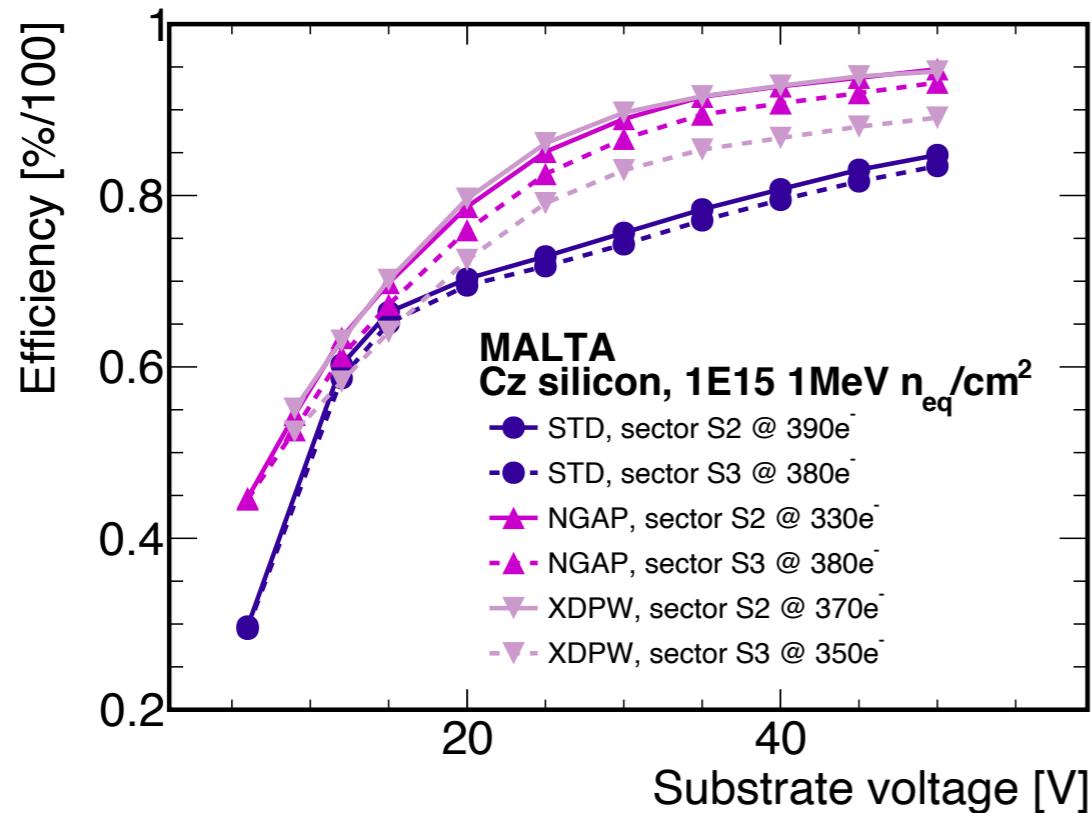
# MALTA irradiated chips

- Cz silicon sensor: higher radiation hardness
- smooth dependency of efficiency (and cluster size) vs substrate voltage
- max efficiency with irradiated chip (n-gap @ $2e^{15} n_{eq}/cm^2$ ) ~93%



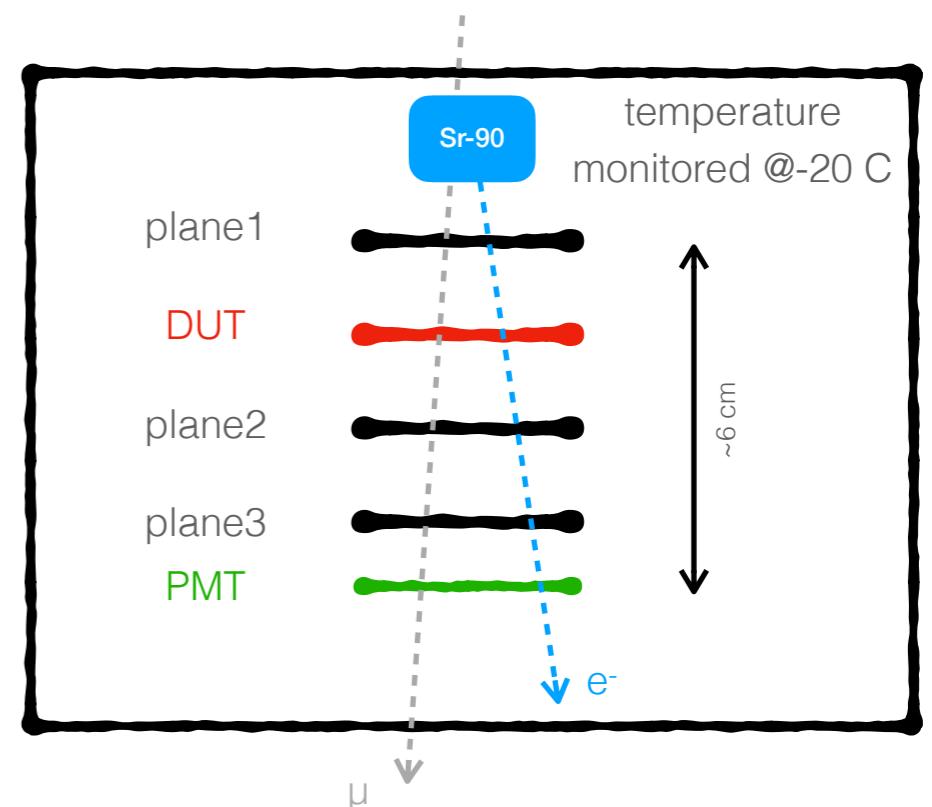
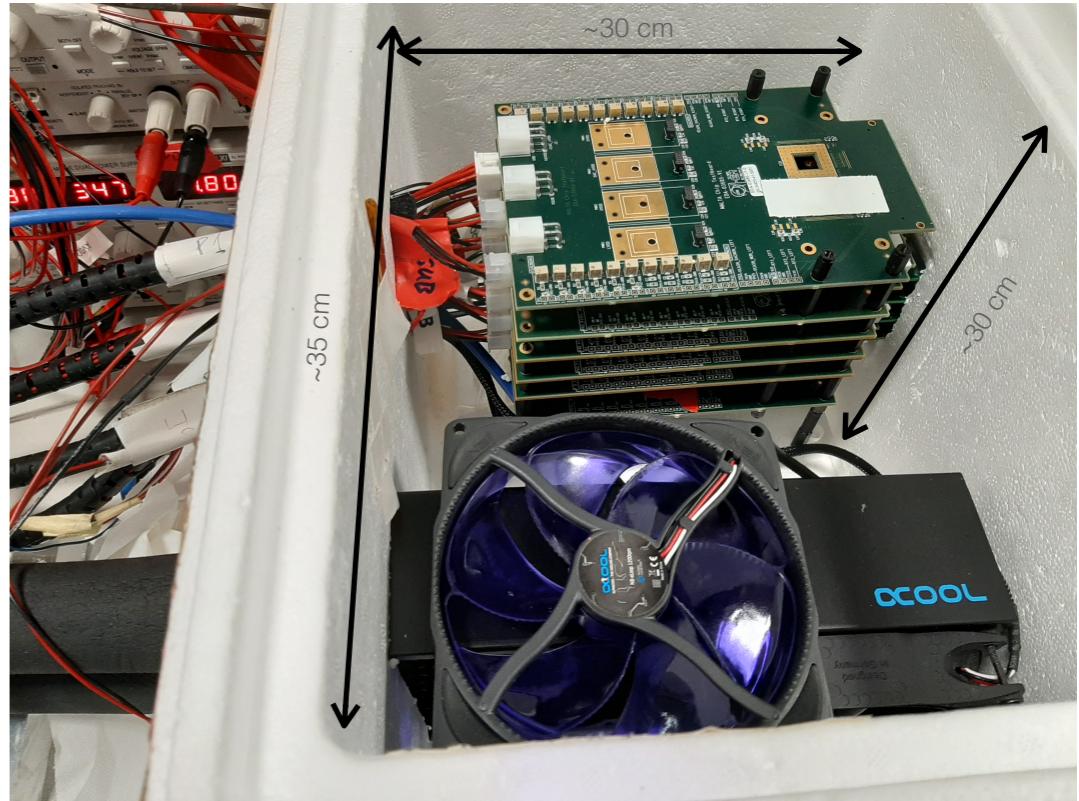
# MALTA irradiated chips

- Cz sensors comparison
- at similar (high value) of threshold:
  - larger efficiency ~95% (n-gap and xdpw) vs 85% (std)
  - larger cluster size



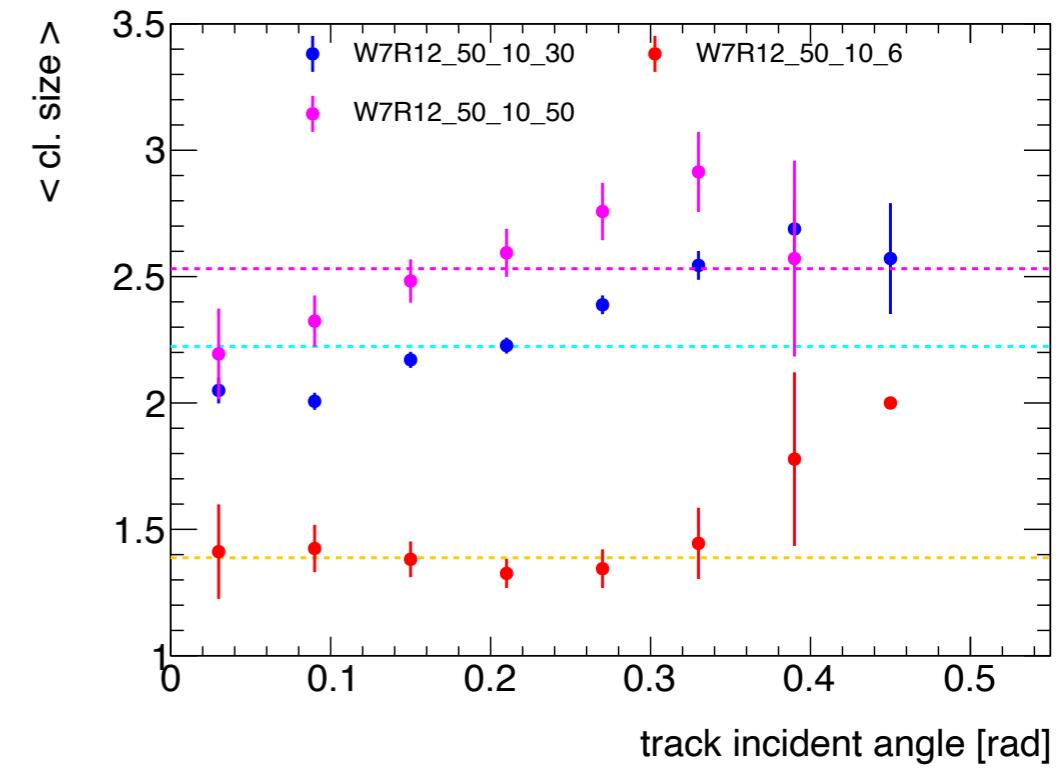
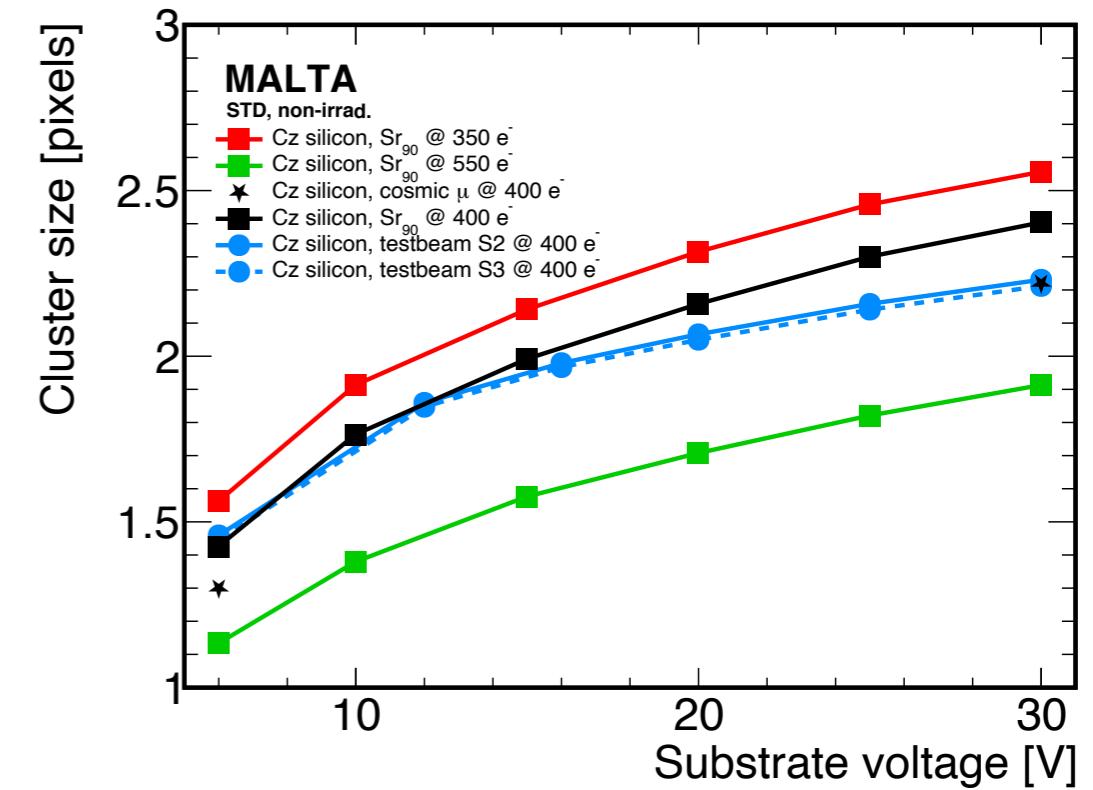
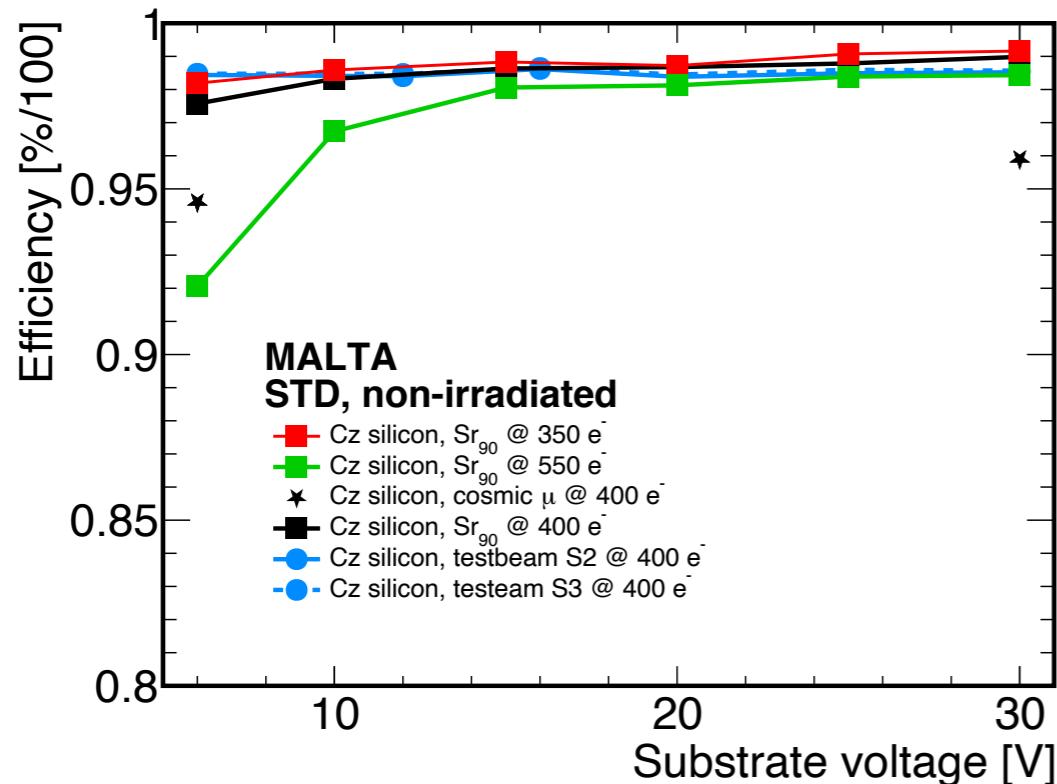
# MALTA telescope 2020

- telescope for lab measurements
- 4 MALTA planes and one PMT
- PicoTDC for timing measurements
- different runs:
  - cosmic muons: high resolution but very low rate  $1\mu/6'$
  - low energy electrons Sr-90: high rate but high multiple scattering
- entire telescope in a cold box
- powerful setup to test new chips
- development of DAQ, DQ and trigger logic for future testbeam



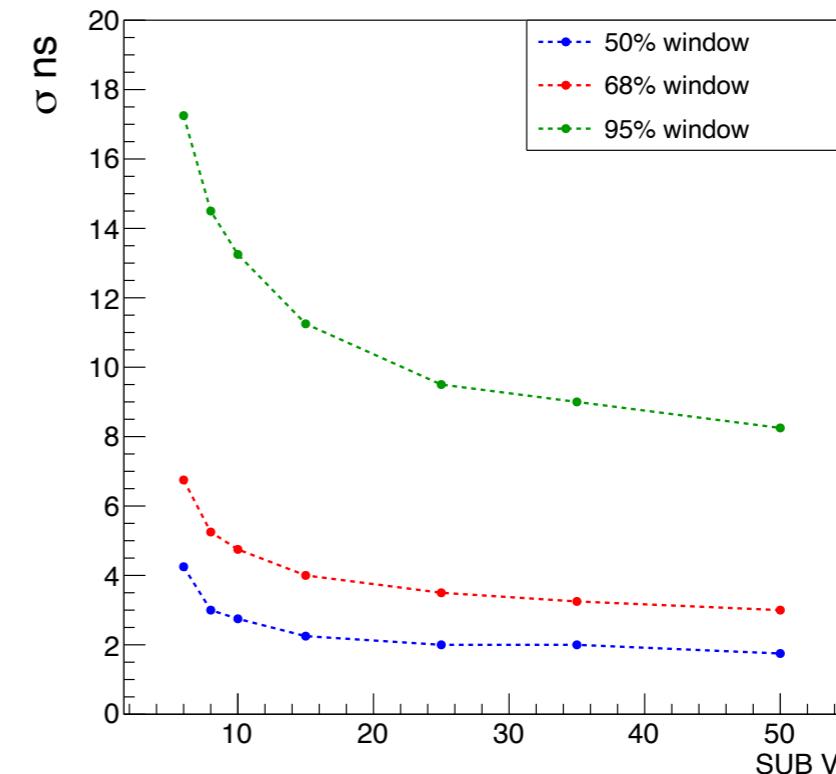
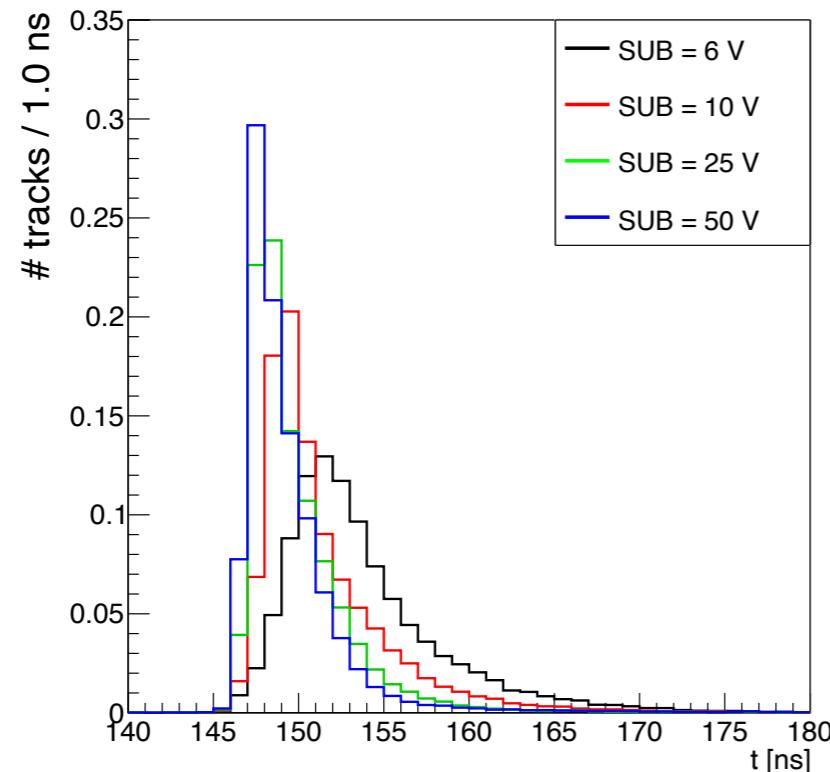
# MALTA lab measurements

- measurement of efficiency and cluster size with cosmic muons and Sr-90
- good behavioural agreement with the testbeam, difference due to:
  - “beam” condition (testbeam  $\sim 3\text{GeV}$   $e^-$  vs Sr-90  $\sim 2\text{-}3 \text{ MeV } e^-$ )
  - not perfect alignment for  $\mu$



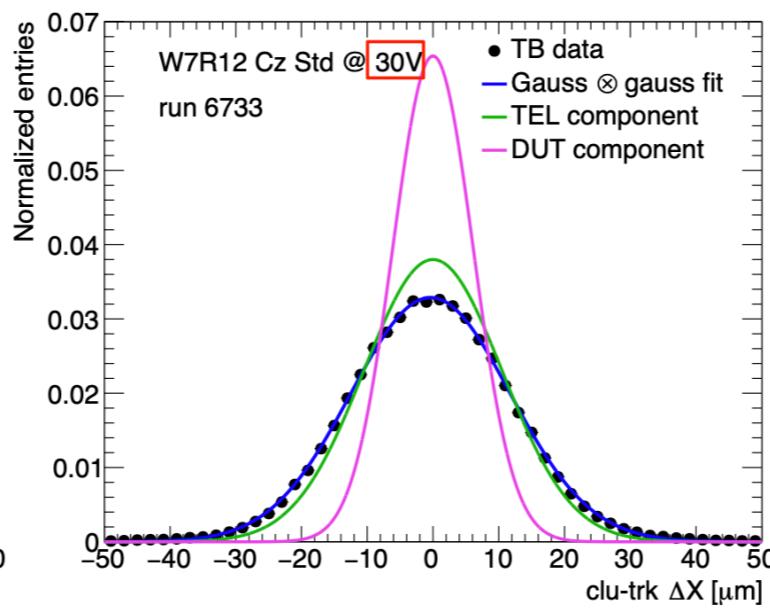
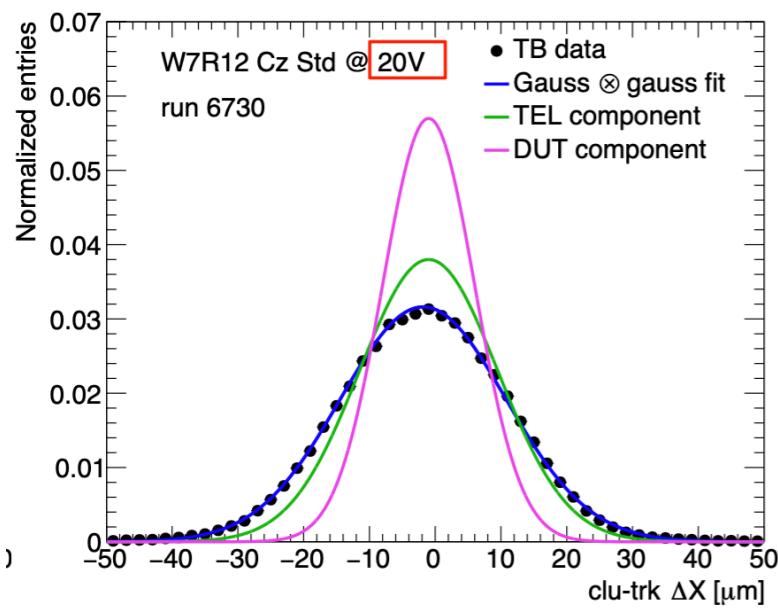
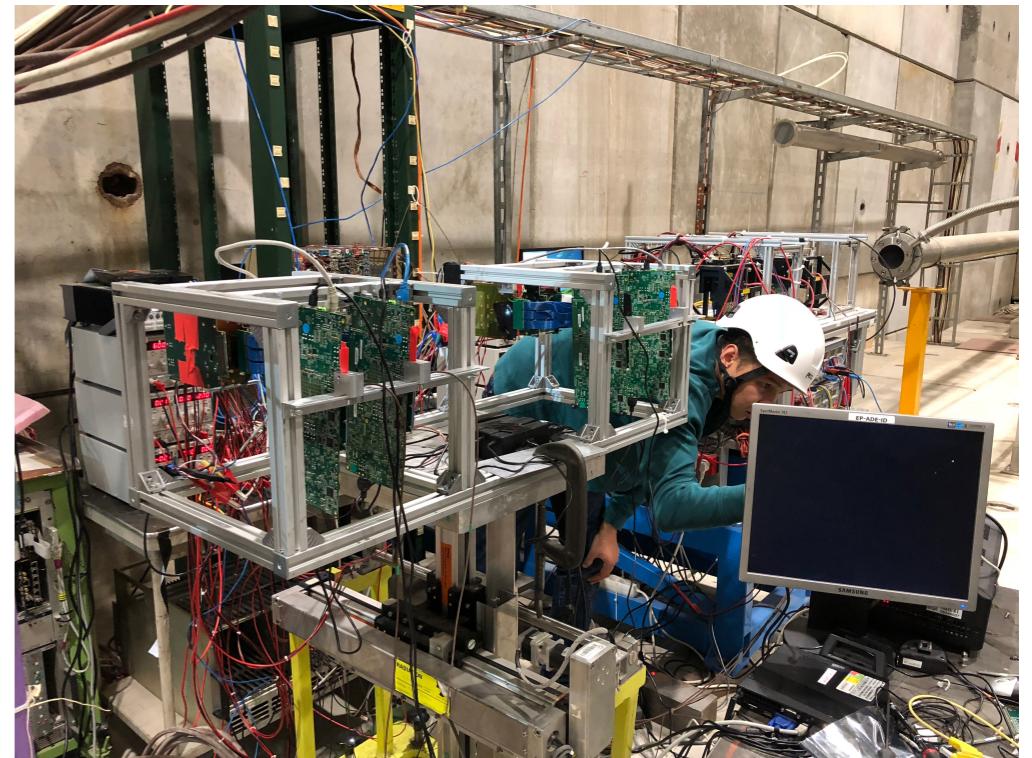
# MALTA timing measurements

- PicoTDC used to measure  $\Delta t$  ( $t_{\text{MALTA}} - t_{\text{PMT}}$ ): time of the fastest hit of the cluster (matched with the track in the DUT) - time of the hit in the scintillator  $\sigma_{\text{PMT}} \sim 1$  ns (not subtracted)
- study the dependency of  $\Delta t$  as a function of substrate voltage and threshold
- define 3 integral windows which contain the **50%-68%-95%** of the  $\Delta t$  distribution



# MALTA testbeam 2021

- waiting for approval @ SPS
- standalone MALTA based telescope:
  - cooling, trigger logic, software, etc..
- possible improvement, use Cz samples as tracking planes:
  - better spatial resolution at -30 V due to larger cluster size



	Epi Std	Cz Std	Cz std	Cz std
SUB V	-6	-6	-20	-30
X-res $\mu m$	$\sim 10.5$	$\sim 9.3$	$\sim 7.0$	$\sim 6.1$

back-of-the-envelope calculation

# conclusions

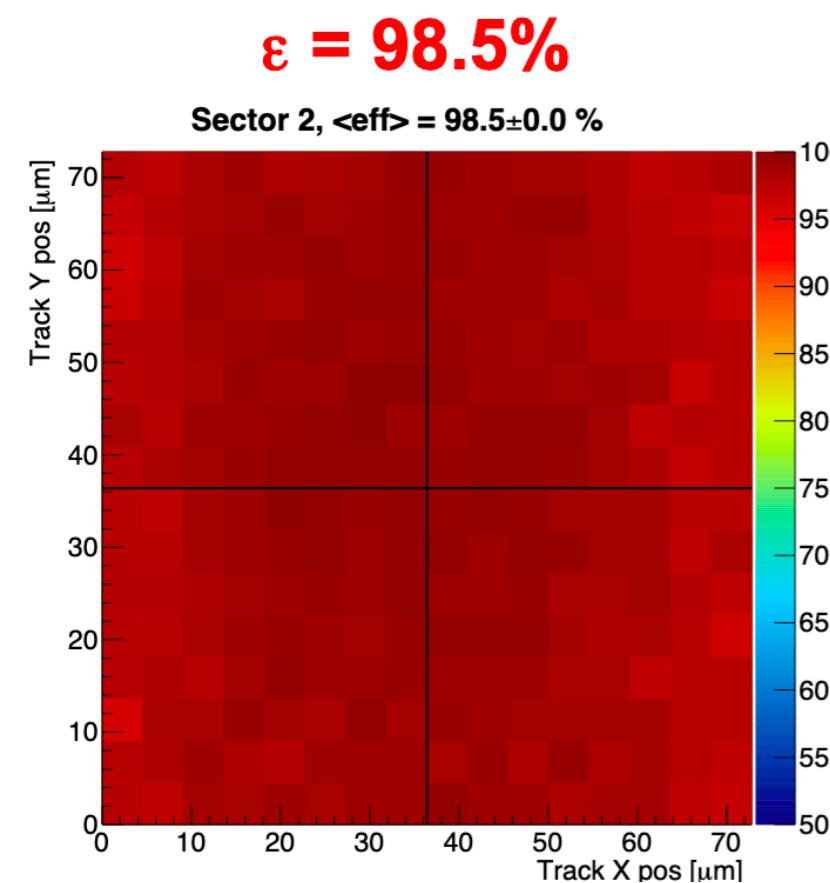
- development of the MALTA CMOS pixel sensors (TowerJazz 180 nm technology)
- MALTA very efficient after neutron irradiation (up to  $2 \times 10^{15} n_{eq}/cm^2$ )
- continue integrating MALTA in performing telescope systems
- more results from DESY 2019 test beam still to come
- testbeam @SPS in 2021
- MALTA2 (wafer arrived at CERN)  
with better front-end: larger  
transistors and cascode frontend  
--> larger gain and improved noise  
performance



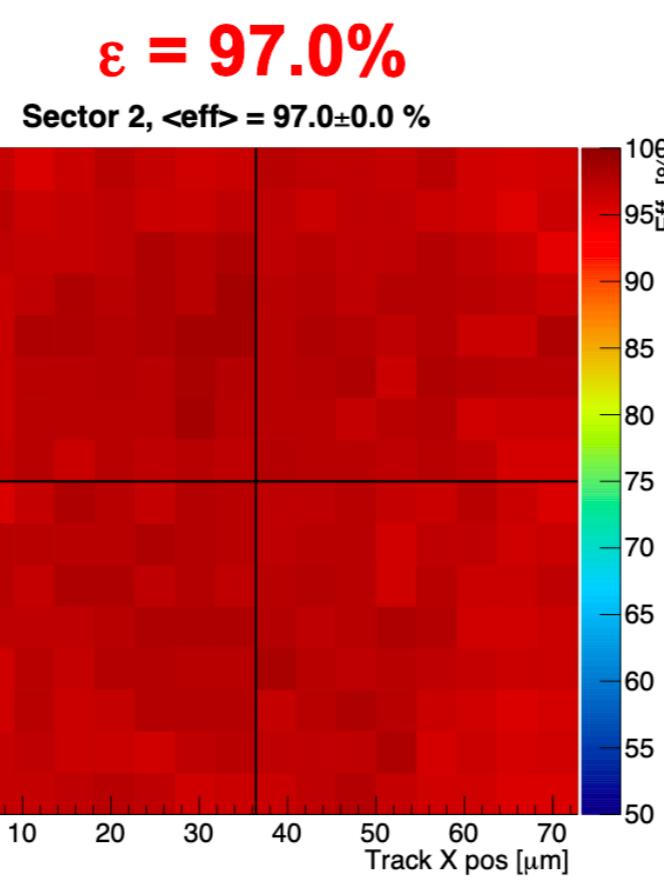
# extra slides

# In-pixel efficiency

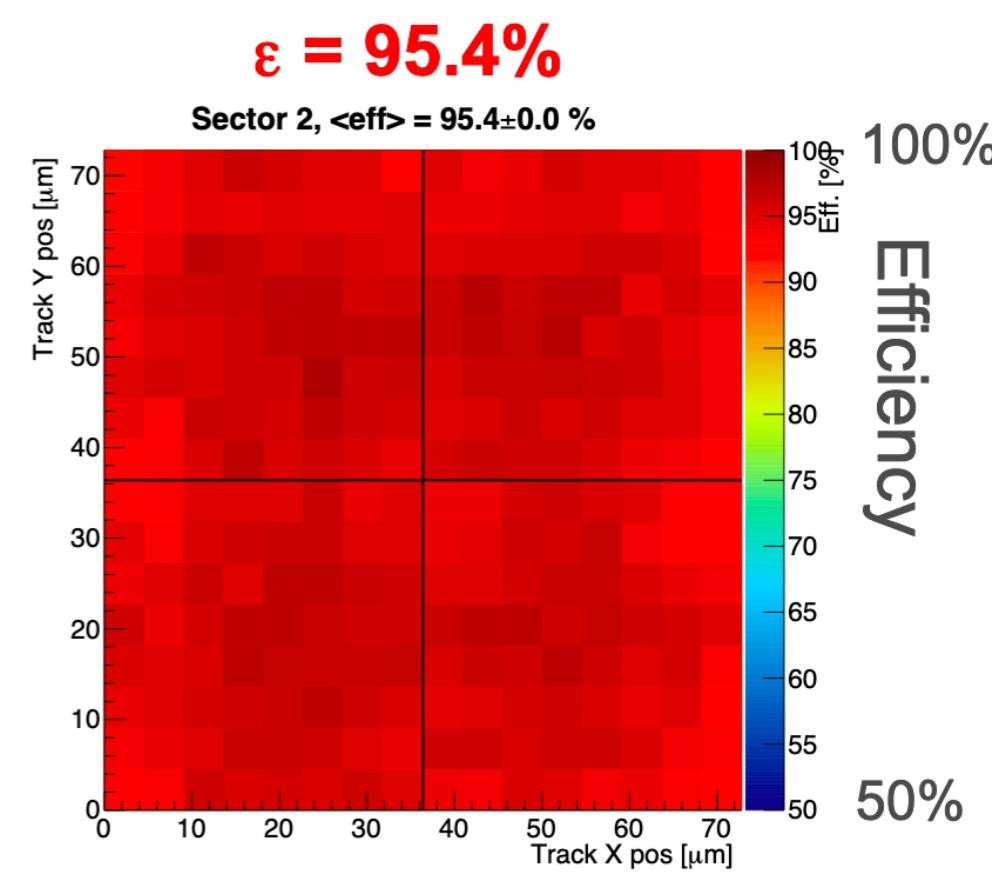
**MALTA Cz**  
unirradiated



**MALTA Cz n-gap**  
 $1 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$

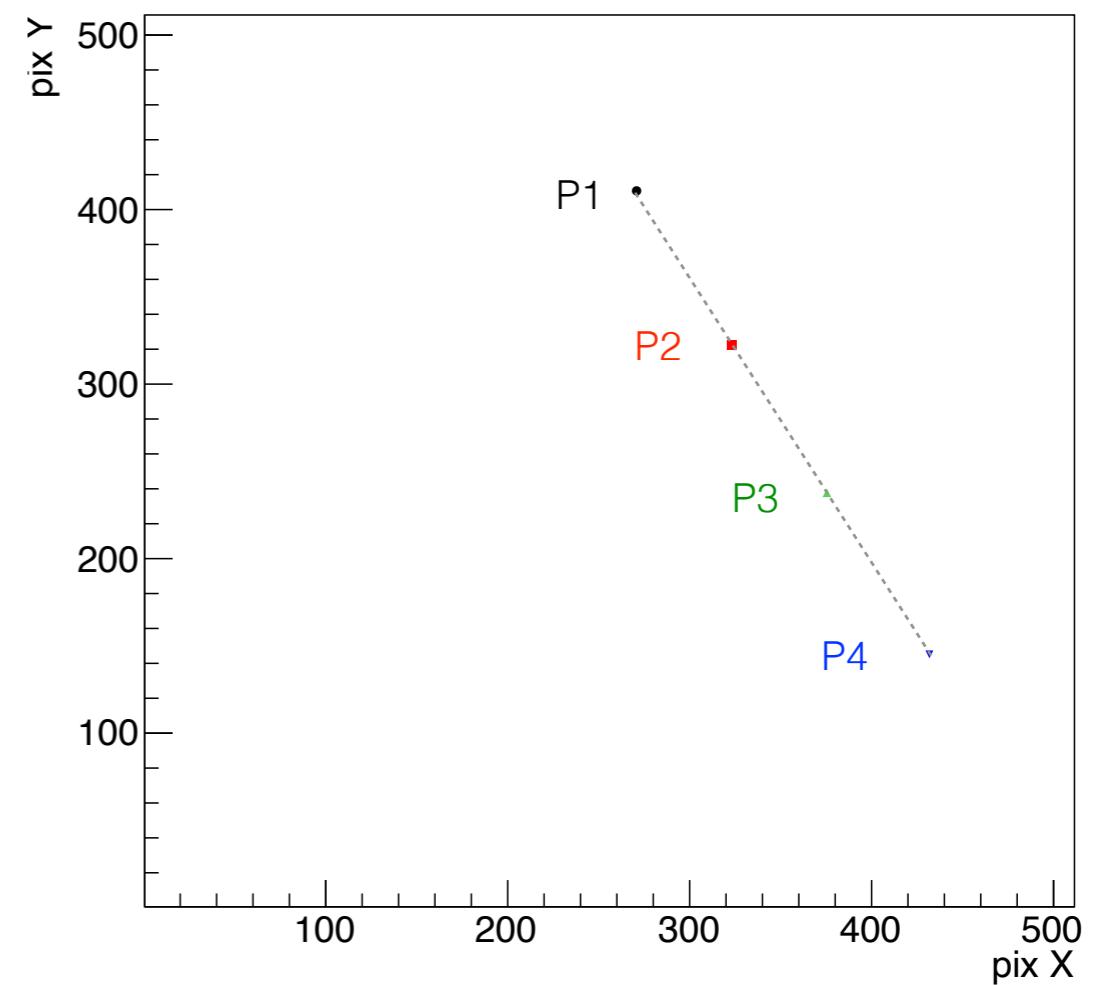
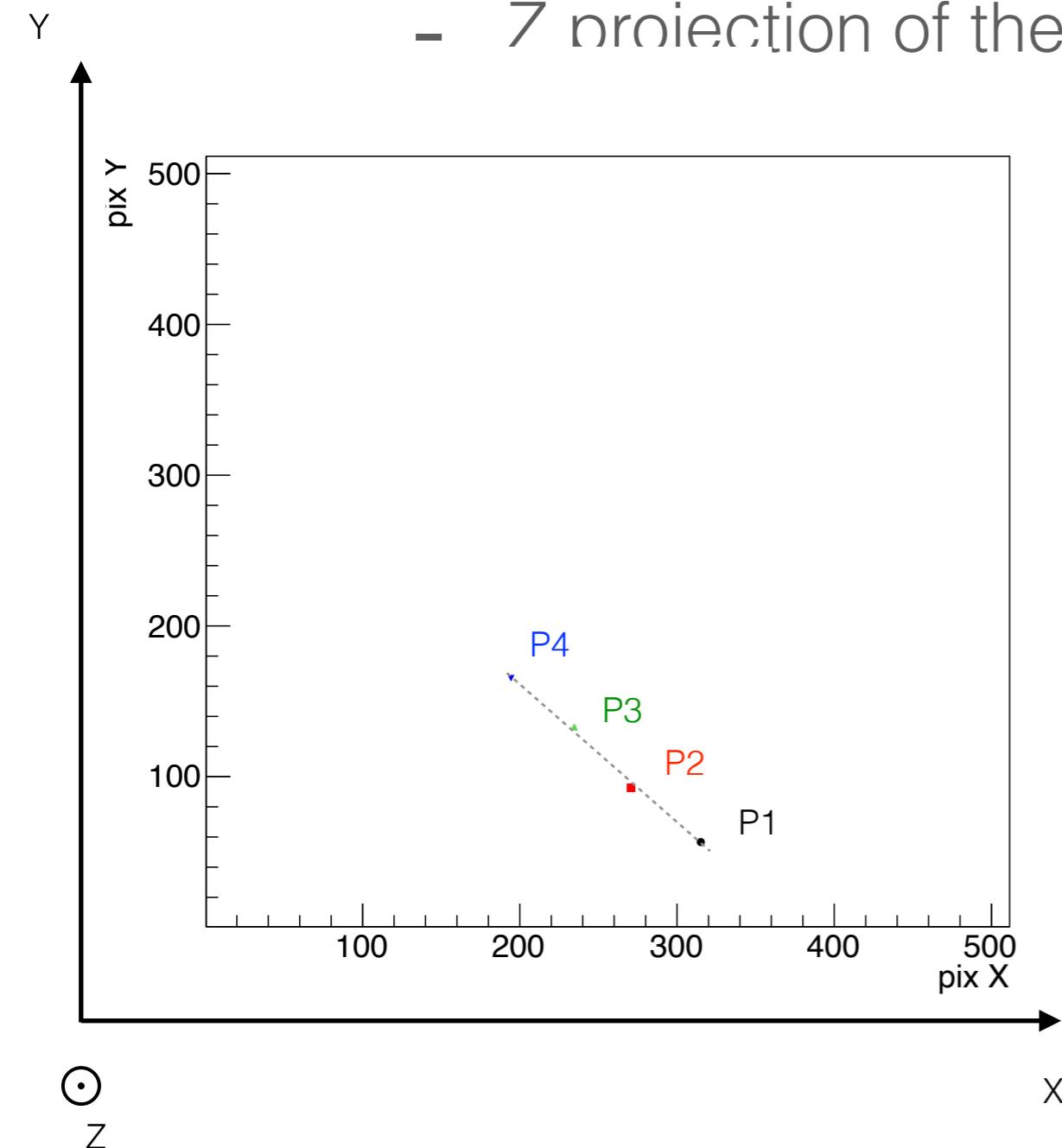


**MALTA Cz n-gap**  
 $2 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$



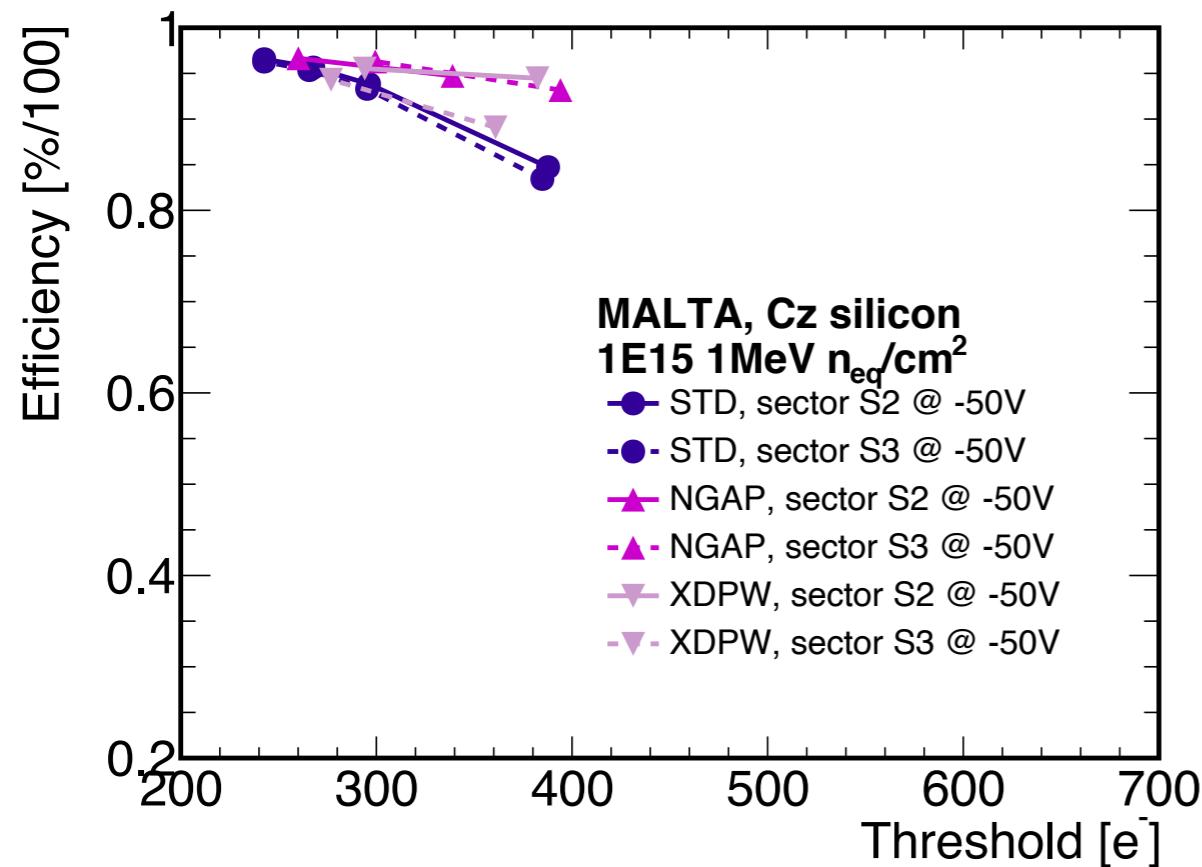
# cosmic muon

-  $\pi$  projection of the 4 telescope planes

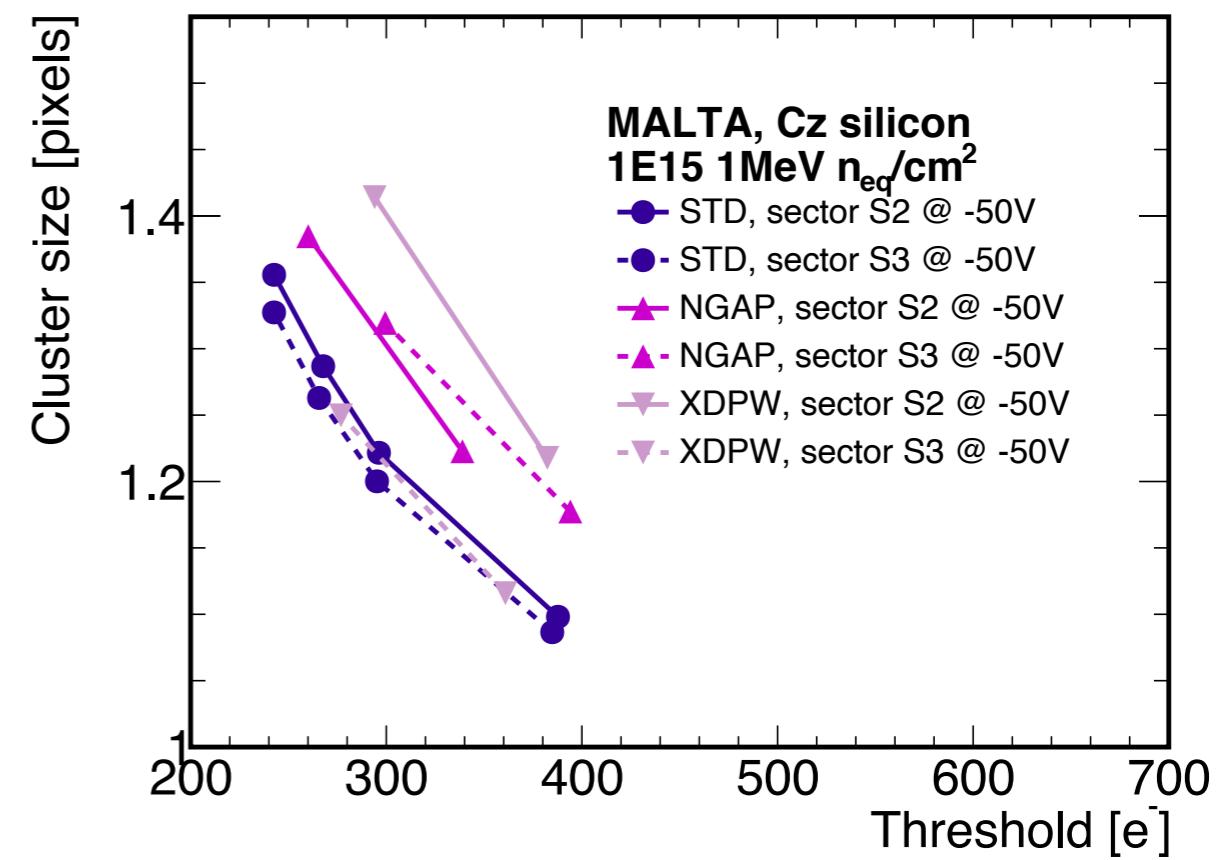


# Cz irradiated chips

efficiency vs threshold

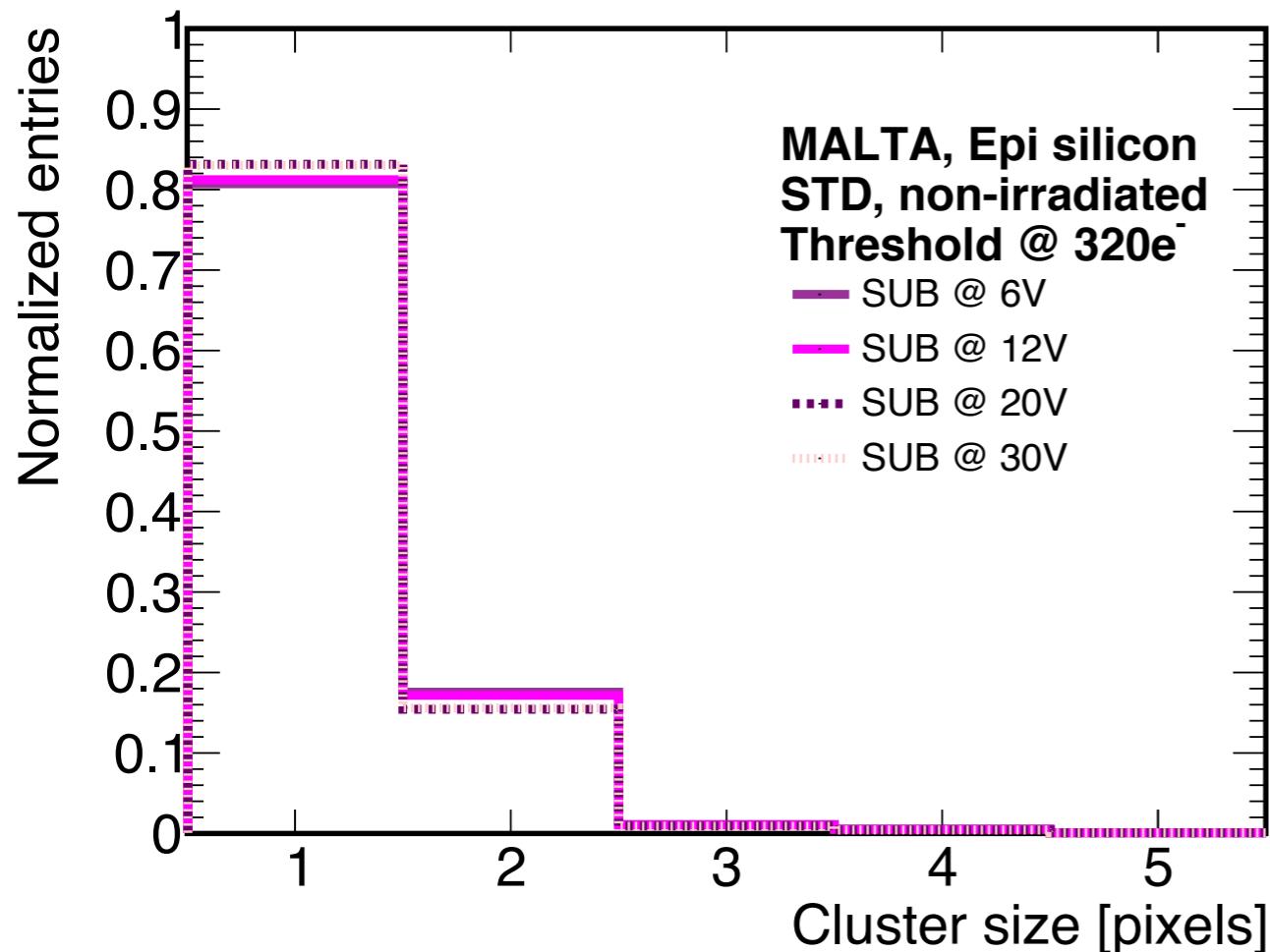


cluster size vs threshold

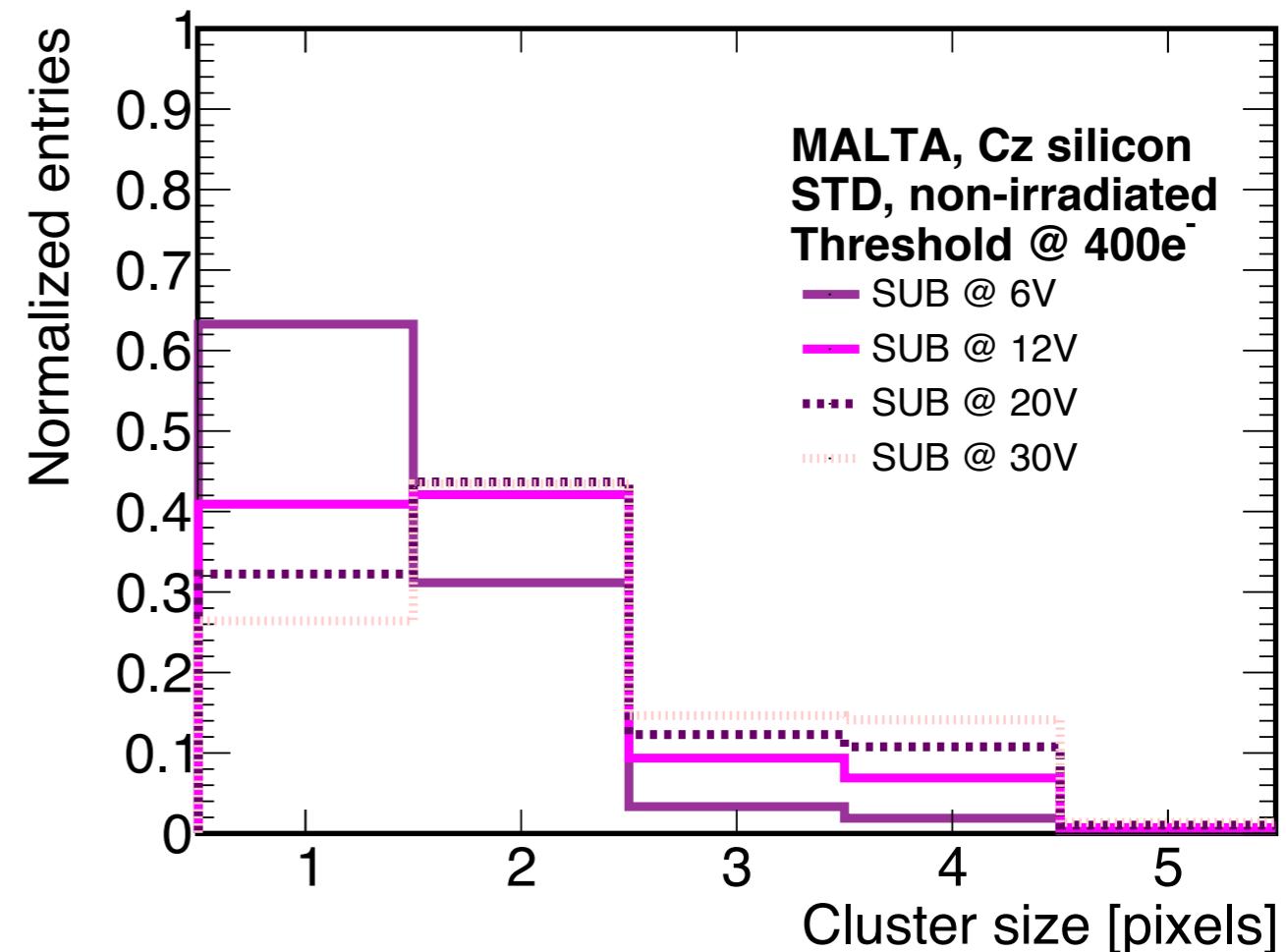


# non irradiated chips

std Epi silicon



std Cz silicon



# MALTA history 2

